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MINIMAL THICKNESS COATINGS

by

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We wish to determine how the application of a very thin layer of highly conducting material affects the scattering behavior of a dielectric body. Since the only shape for which the analysis can be carried out exactly is a sphere, the specific problem treated is that of a sphere composed of a pure (lossless) homogeneous isotropic dielectric covered with a uniform metallic layer whose thickness  $d$  is less than the skin depth  $\delta$  in the metal. The body is illuminated by a plane electromagnetic wave and attention will be confined to the far zone scattered fields in the back and forward directions for sphere sizes close to resonance:  $k_o a \leq 2$  where  $k_o$  is the free space propagation constant and  $a$  is the radius of the dielectric core.

General Formulation

It is convenient to examine first the general problem in which no assumptions are made about the constitutive parameters of the sphere or its coating. To this end, consider a sphere of radius  $a$  whose permittivity and permeability are  $\epsilon_1$  and  $\mu_1$  respectively which is coated with a uniform layer of thickness  $d$  whose constitutive parameters are  $\epsilon_2$  and  $\mu_2$ . The whole is immersed in free space and illuminated by a plane electromagnetic wave polarised in the  $x$  direction and propagating along the  $-z$  axis (see Fig. 1). We can then write

$$\underline{E}^i = \hat{x} e^{-ik_o z}, \quad \underline{H}^i = -Y_o \hat{y} e^{-ik_o z} \quad (1)$$

where  $Y_o = 1/Z_o$  is the intrinsic admittance of free space. Mks units are employed and a time factor  $e^{-i\omega t}$  suppressed.

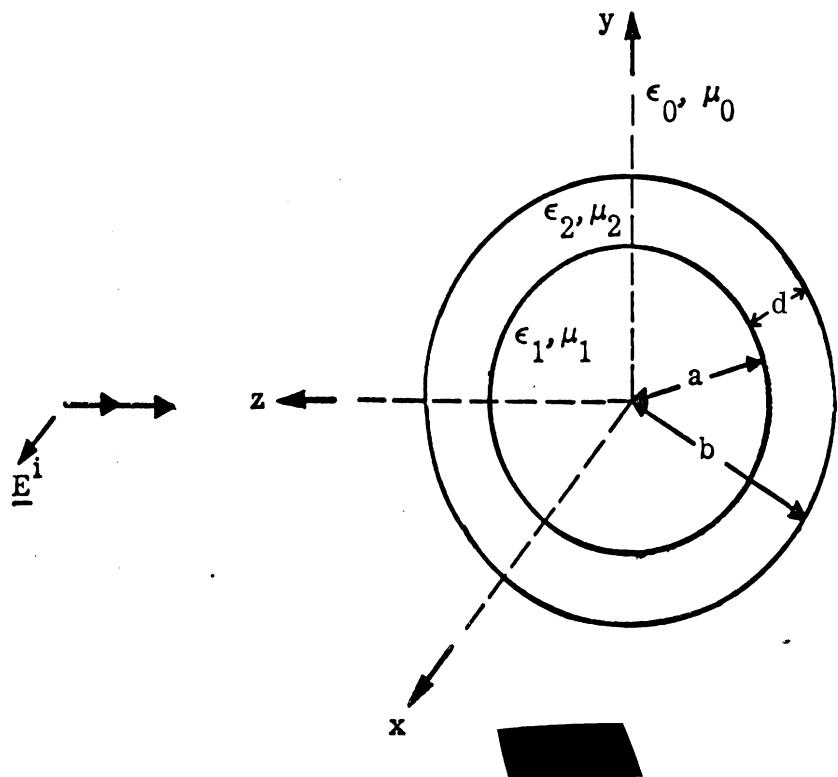


FIG. 1: The geometry.

General expressions for the scattered field are readily available in the literature (see, for example, Goodrich et al, 1961; p. 13 et seq.) and when these are particularised to the cases of far zone scattering in the backward ( $\theta = 0$ ) and forward ( $\theta = \pi$ ) directions, it is found that

$$S(0) = i \sum_{n=1}^{\infty} (-1)^n \left(n + \frac{1}{2}\right) (A_n - B_n) , \quad (2)$$

$$S(\pi) = i \sum_{n=1}^{\infty} \left(n + \frac{1}{2}\right) (A_n + B_n) , \quad (3)$$

where  $S$  is the far field amplitude, i.e. the coefficient of  $\hat{x} \frac{e^{ik_o r}}{k_o r}$  in the far zone. The coefficients  $A_n$  and  $B_n$  can be written as

$$A_n = \frac{\psi_n(k_o b) + \Gamma_n^{(1)} \psi'_n(k_o b)}{\xi_n(k_o b) + \Gamma_n^{(1)} \xi'_n(k_o b)} \quad (4)$$

$$B_n = \frac{\psi_n(k_o b) - \Gamma_n^{(2)} \psi'_n(k_o b)}{\xi_n(k_o b) - \Gamma_n^{(2)} \xi'_n(k_o b)} \quad (5)$$

where

$$\begin{aligned} \psi_n(z) &= z j_n(z) = \sqrt{\frac{\pi z}{2}} J_{n+1/2}(z) , \\ \xi_n(z) &= z h_n^{(1)}(z) = \sqrt{\frac{\pi z}{2}} H_{n+1/2}^{(1)}(z) \end{aligned} \quad (6)$$

are modified spherical Bessel and Hankel functions. The primes denote differentiation with respect to the entire argument. In eqs. (4) and (5)

$$\Gamma_n^{(1)} = -\frac{Z_2}{Z_o} \frac{Z_1 P_1 - Z_2 P_3}{Z_1 P_2 - Z_2 P_4} \quad (7)$$

$$\Gamma_n^{(2)} = \frac{Z_2}{Z_o} \frac{Y_1 P_2 - Y_2 P_4}{Y_1 P_1 - Y_2 P_3} \quad (8)$$

where

$$\begin{aligned} P_1 &= \psi_n(k_1 a) \left\{ \psi'_n(k_2 a) \xi_n(k_2 b) - \xi'_n(k_2 a) \psi_n(k_2 b) \right\} , \\ P_2 &= \psi_n(k_1 a) \left\{ \psi'_n(k_2 a) \xi'_n(k_2 b) - \xi'_n(k_2 a) \psi'_n(k_2 b) \right\} , \\ P_3 &= \psi'_n(k_1 a) \left\{ \psi_n(k_2 a) \xi_n(k_2 b) - \xi_n(k_2 a) \psi_n(k_2 b) \right\} , \end{aligned} \quad (9)$$

$$P_4 = \psi_n'(k_1 a) \left\{ \psi_n(k_2 a) \xi_n'(k_2 b) - \xi_n(k_2 a) \psi_n'(k_2 b) \right\} .$$

$Z_i = 1/Y_i$  and  $k_i$  are the characteristic impedance and propagation constant, respectively, of the  $i$ th medium and have the usual definitions

$$Z_i = \sqrt{\frac{\mu_i}{\epsilon_i}} , \quad k_i = \omega \sqrt{\mu_i \epsilon_i} \quad (10)$$

where  $\epsilon_i$  and  $\mu_i$  are the electromagnetic constitutive parameters which may be complex.

It is of interest to examine the above results in certain special cases. If  $b = a$ , i.e. the layer thickness  $d = b - a$  is zero,

$$P_2 = P_3 = 0$$

and

$$\frac{P_1}{P_4} = - \frac{\psi_n(k_1 a)}{\psi_n'(k_1 a)} .$$

Hence

$$\begin{aligned} \Gamma_n^{(1)} &= - \frac{Z_1}{Z_o} \frac{\psi_n(k_1 a)}{\psi_n'(k_1 a)} , \\ \Gamma_n^{(2)} &= \frac{Z_1}{Z_o} \frac{\psi_n'(k_1 a)}{\psi_n(k_1 a)} \end{aligned} \quad (11)$$

and the expressions for  $A_n$  and  $B_n$  reduce to those for a homogeneous sphere of radius  $a$ , as required. On the other hand, if the core is perfectly conducting ( $\text{Im } \epsilon_1 = \infty$ ),  $Z_1 = 0$  and

$$\Gamma_n^{(1)} = - \frac{Z_2}{Z_o} \frac{P_3}{P_4} , \quad \Gamma_n^{(2)} = \frac{Z_2}{Z_o} \frac{P_2}{P_1} \quad (12)$$

These ratios are independent of  $k_1$ , as expected, and the resulting expressions for  $A_n$  and  $B_n$  are those for a coated metal sphere (see, for example, Scharfman, 1954.) Finally, we note that if the coating is perfectly conducting ( $\text{Im } \epsilon_2 = \infty$ ),  $Z_2 = 0$  and

$$\Gamma_n^{(1)} = \Gamma_n^{(2)} = 0 . \quad (13)$$

The expressions for  $A_n$  and  $B_n$  are then identical to those for a perfectly conducting sphere of radius  $b$ . This last is a limiting case of the situation we are called upon to investigate, and a particular virtue of the expressions we have adopted is that as the layer thickness increases,  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$  (whose computation is the crux of the problem) both approach zero.

### Modal Impedances

The quantities  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$  have a certain physical interpretation an appreciation of which is important in understanding the effect of the coating. Specifically,  $i\Gamma_n^{(1)}$  and  $i\Gamma_n^{(2)}$  are the effective surface impedances of the  $n$ th magnetic and electric modes respectively. To make this point more clear, consider a sphere of radius  $b$  at the surface of which the boundary condition is

$$\underline{E} - (\underline{E} \cdot \hat{n}) \hat{n} = \eta Z_o \hat{n} \wedge \underline{H} \quad (14)$$

where  $\hat{n}$  is a unit normal in the outwards (radial) direction. On solving the boundary value problem, it is found that

$$A_n = \frac{\psi_n(k_o b) - i\eta\psi'_n(k_o b)}{\xi_n(k_o b) - i\eta\xi'_n(k_o b)} , \quad (15)$$

$$B_n = \frac{\psi'_n(k_0 b) + i\eta \psi_n(k_0 b)}{\xi'_n(k_0 b) + i\eta \xi_n(k_0 b)} \quad (16)$$

and comparison of (15) and (16) with (4) and (5) then leads to the above interpretation of  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$ .

Let us now examine the effect on  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$  of increasing the propagation constant  $k_2$  of the layer material. Such an increase can be achieved either by increasing the real part of the permittivity (or permeability) or, as in the case of direct interest to us, by increasing the conductivity. Since

$$\begin{aligned} \xi_n(z) &\sim (-i)^{n+1} e^{iz} \left\{ 1 - \frac{n(n+1)}{2iz} \right\}, \\ \xi'_n(z) &\sim i \xi_n(z) \\ \psi_n(z) &= \frac{1}{2} \left\{ \xi_n(z) + \overline{\xi_n(z)} \right\} \\ &\sim \frac{1}{2} (-i)^{n+1} e^{iz} \left\{ 1 - \frac{n(n+1)}{2iz} \right\} + \frac{1}{2} i^{n+1} e^{-iz} \left\{ 1 + \frac{n(n+1)}{2iz} \right\} \\ \psi'_n(z) &\sim \frac{i}{2} \left\{ \xi_n(z) - \overline{\xi_n(z)} \right\} \end{aligned}$$

as  $|z| \rightarrow \infty$ , it follows that if  $|k_2|a \gg 1$  implying  $|k_2|b \gg 1$  a fortiori,

$$\begin{aligned} \psi_n(k_2 b) \xi_n(k_2 a) &\sim \frac{1}{2} e^{-ik_2 d} \left\{ 1 - \frac{n(n+1)d/a}{2ik_2 b} \right\} \\ &\quad + \frac{1}{2} (-1)^{n+1} e^{ik_2(a+b)} \left\{ 1 - \frac{n(n+1)(2+d/a)}{2ik_2 b} \right\} \end{aligned}$$

with similar expressions for the other combinations of functions occurring in the formulae for  $P_1, \dots, P_4$ . Hence

$$\begin{aligned}
 P_1 &\sim -i \left\{ \cos k_2 d + \frac{n(n+1)d/a}{2k_2 b} \sin k_2 d \right\} \psi_n(k_1 a) \\
 P_2 &\sim i \left\{ \sin k_2 d - \frac{n(n+1)d/a}{2k_2 b} \cos k_2 d \right\} \psi_n(k_1 a) \\
 P_3 &\sim i \left\{ \sin k_2 d - \frac{n(n+1)d/a}{2k_2 b} \cos k_2 d \right\} \psi'_n(k_1 a) \\
 P_4 &\sim i \left\{ \cos k_2 d + \frac{n(n+1)d/a}{2k_2 b} \sin k_2 d \right\} \psi'_n(k_1 a)
 \end{aligned} \tag{17}$$

and we note that the terms  $O(\frac{1}{k_2 b})$  are all proportional to  $d/a$ . The eqs. (17) are valid regardless of the layer thickness and if  $d/a \ll 1$ , as is certainly true in the present problem, the second term in each of the above expressions can be neglected\* in comparison with the first, yielding

$$\begin{aligned}
 \frac{P_1}{\psi_n(k_1 a)}, \quad -\frac{P_4}{\psi'_n(k_1 a)} &\sim -i \cos k_2 d \\
 \frac{P_2}{\psi_n(k_1 a)}, \quad \frac{P_3}{\psi'_n(k_1 a)} &\sim i \sin k_2 d
 \end{aligned} \tag{18}$$

from which we obtain

$$\Gamma_n^{(1)} \sim \frac{Z_2}{Z_o} \cot(k_2 d - \gamma_n^{(1)}) \tag{19}$$

$$\Gamma_n^{(2)} \sim \frac{Z_2}{Z_o} \cot(k_2 d + \gamma_n^{(2)}) \tag{20}$$

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\* An exception occurs if  $k_2 d$  is an odd or even integer multiple of  $\pi/2$ , but this is possible only if  $k_2$  is real.

where

$$\tan \gamma_n^{(1)} = \frac{Z_2}{Z_1} \frac{\psi_n'(k_1 a)}{\psi_n(k_1 a)} , \quad (21)$$

$$\tan \gamma_n^{(2)} = \frac{Z_2}{Z_1} \frac{\psi_n(k_1 a)}{\psi_n'(k_1 a)} . \quad (22)$$

As long as  $\gamma_n^{(1)}$  and  $\gamma_n^{(2)}$  differ from zero, the effective surface impedances of the electric and magnetic modes differ and vary with the mode number. As

$Z_2/Z_1 \rightarrow 0$ , however,

$$\gamma_n^{(1)}, \gamma_n^{(2)} \rightarrow 0$$

and

$$\Gamma_n^{(1)}, \Gamma_n^{(2)} \rightarrow \frac{Z_2}{Z_o} \cot k_2 d \quad (23)$$

corresponding to a single surface impedance

$$\eta = i \frac{Z_2}{Z_o} \cot k_2 d . \quad (24)$$

This is identical to the surface impedance of a highly conducting slab of thickness  $d$  illuminated by a plane wave at normal incidence. It should be noted that as

$Z_2/Z_1 \rightarrow 0$ , the impedance  $\eta$  of eq. (24) also approaches zero unless  $k_2 d$  is maintained small by progressively reducing the layer thickness. In the latter case,

$$\eta \rightarrow i \frac{\epsilon_o}{\epsilon_2} \frac{1}{k_o d} . \quad (25)$$

### Low Frequency Scattering

The only situation in which we can arrive at an analytical expression for the scattered field is the low frequency one in which  $k_1 a, k_0 b \ll 1$ . Since

$$\xi_n(z) = O(z^{-n}) , \quad \psi_n(z) = O(z^{n+1})$$

for  $z \ll 1$ , it is evident from eqs. (4) and (5) that only the lowest order ( $n=1$ ) modes now contribute to the leading term in the expansion for the far zone scattered field. This is the Rayleigh scattering regime in which the scattered field is attributable to the induced electric and magnetic dipoles; and since

$$\xi_1(z) = -\frac{i}{z} \left\{ 1 + O(z^2) \right\} , \quad \psi_1(z) = \frac{z^2}{3} \left\{ 1 + O(z^2) \right\} , \quad (26)$$

we have

$$A_1 = -\frac{2i}{3} (k_0 b)^3 \left\{ \frac{\Gamma_1^{(1)} + \frac{1}{2} k_0 b}{\Gamma_1^{(1)} - k_0 b} + O(\overline{k_0 b}^2) \right\} , \quad (27)$$

$$B_1 = -\frac{2i}{3} (k_0 b)^3 \left\{ \frac{1 - \frac{1}{2} k_0 b \Gamma_1^{(2)}}{1 + k_0 b \Gamma_1^{(2)}} + O(\overline{k_0 b}^2) \right\} . \quad (28)$$

Hence

$$S(0) = -(k_0 b)^3 \left\{ \frac{\Gamma_1^{(1)} + \frac{1}{2} k_0 b}{\Gamma_1^{(1)} - k_0 b} - \frac{1 - \frac{1}{2} k_0 b \Gamma_1^{(2)}}{1 + k_0 b \Gamma_1^{(2)}} + O(\overline{k_0 b}^2) \right\} \quad (29)$$

$$S(\pi) = (k_0 b)^3 \left\{ \frac{\Gamma_1^{(1)} + \frac{1}{2} k_0 b}{\Gamma_1^{(1)} - k_0 b} + \frac{1 - \frac{1}{2} k_0 b \Gamma_1^{(2)}}{1 + k_0 b \Gamma_1^{(2)}} + O(\overline{k_0 b}^2) \right\} \quad (30)$$

and in the particular case  $\Gamma_1^{(1)} = \Gamma_1^{(2)} = 0$ ,

$$\begin{aligned} S(0) &= \frac{3}{2} (k_o b)^3 \left\{ 1 + O(k_o b^2) \right\}, \\ S(\pi) &= \frac{1}{2} (k_o b)^3 \left\{ 1 + O(k_o b^2) \right\}, \end{aligned} \quad (31)$$

in agreement with the known results (Bowman et al, 1969; p. 406) for a perfectly conducting sphere.

Let us now examine the expressions for  $\Gamma_1^{(1)}$  and  $\Gamma_1^{(2)}$  when the layer is highly conducting but very thin. Since  $|k_2|a$  is then large, the formulae (19) and (20) for  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$  apply, and when  $k_1 a \ll 1$ ,

$$\begin{aligned} \tan \gamma_1^{(1)} &= \frac{Z_2}{Z_1} \frac{2}{k_1 a} \left\{ 1 + O(k_1 a)^2 \right\}, \\ \tan \gamma_1^{(2)} &= \frac{Z_2}{Z_1} \frac{k_1 a}{2} \left\{ 1 + O(k_1 a)^2 \right\}. \end{aligned}$$

Hence

$$\Gamma_1^{(1)} = \frac{Z_2}{Z_o} \frac{Z_1 k_1 a + 2 Z_2 \tan k_2 d}{Z_1 k_1 a \tan k_2 d - 2 Z_2}$$

and if  $|k_2 d|$  is sufficiently small for us to write  $\tan k_2 d \approx k_2 d$ ,

$$\Gamma_1^{(1)} \approx -\frac{\mu_1}{\mu_o} \frac{k_o a}{2} \frac{1 + 2 \frac{\mu_2}{\mu_1} \frac{d}{a}}{1 - \frac{1}{2} \frac{\mu_1}{\mu_2} k_2 a k_2 d}. \quad (32)$$

Similarly

$$\begin{aligned} \Gamma_1^{(2)} &= \frac{\mu_1}{\mu_0} \frac{k_o}{k_1} \frac{2}{k_1 a} \frac{1 - \frac{1}{2} \frac{\mu_2}{\mu_1} k_1 a k_1 d}{1 + 2 \frac{\mu_1}{\mu_2} \left(\frac{k_2}{k_1}\right)^2 \frac{d}{a}} \\ &\approx \frac{\mu_1}{\mu_0} \frac{k_o}{k_1} \frac{2}{k_1 a} \frac{1}{1 + 2 \frac{\mu_1}{\mu_2} \left(\frac{k_2}{k_1}\right)^2 \frac{d}{a}} \end{aligned} \quad (33)$$

since  $k_1 d$  is indeed negligible compared with unity.

If, for simplicity, it is assumed that  $\mu_2 = \mu_1 = \mu_0$  the above expressions become

$$\Gamma_1^{(1)} = -\frac{k_o a}{2} \frac{1 + 2 \frac{d}{a}}{1 - \frac{1}{2} k_2 a k_2 d}, \quad (34)$$

$$\Gamma_1^{(2)} = \frac{k_o}{k_1} \frac{2}{k_1 a} \frac{1}{1 + 2 \left(\frac{k_2}{k_1}\right)^2 \frac{d}{a}} \quad (35)$$

and since  $a$  and  $b$  are virtually identical for an electrically thin, highly conducting layer, substitution of (34) and (35) into (27) and (28) gives

$$A_1 = -\frac{i}{9} (k_o b)^3 \frac{k_2 b k_2 d}{1 - \frac{1}{3} k_2 b k_2 d}, \quad (36)$$

$$B_1 = -\frac{2i}{3} (k_o b)^3 \frac{\frac{k_1^2 - k_o^2 + 2k_2^2}{k_1^2 + 2k_o^2 + 2k_2^2} \frac{d}{b}}{b}. \quad (37)$$

As the layer thickness  $d \rightarrow 0$ ,

$$A_1 \rightarrow 0 , \quad (38)$$

$$B_1 \rightarrow -\frac{2i}{3} (k_o b)^3 \frac{N^2 - 1}{N^2 + 2}$$

where  $N = \sqrt{\frac{\epsilon_1}{\epsilon_0}}$  is the refractive index of the dielectric, in agreement with the known results for a dielectric sphere (see, for example, Stratton, 1941; p. 572).

If, on the other hand,  $k_2 \rightarrow \infty$  with  $d \neq 0$ ,

$$A_1 \rightarrow \frac{i}{3} (k_o b)^3 , \quad (39)$$

$$B_1 \rightarrow -\frac{2i}{3} (k_o b)^3 ,$$

and we recover the results for a perfectly conducting sphere.

Our particular interest is in the nature of the transition between these two extremes. Taking first  $A_1$ , we observe that if

$$|k_2 b k_2 d| \ll 3$$

$A_1$  is characteristic of a dielectric sphere, whereas if

$$|k_2 b k_2 d| \gg 3$$

the perfectly conducting value is obtained. In consequence, the transition between the two is centered on

$$|k_2 b k_2 d| \approx 3 . \quad (40)$$

For  $B_1$  the transition is a little harder to specify because of the occurrence of

$k_o$  and  $k_1$  in the expression (37), but to an adequate degree of accuracy it can be assumed centered on

$$\left| \frac{k_2}{k_1} \right|^2 \frac{d}{b} \approx \frac{1}{2} . \quad (41)$$

Since, for a metal,  $\left| k_2 \right|^2 = 2/\delta^2$  where  $\delta$  is the penetration (or skin) depth, the transitional values of  $d/\delta$  are

$$\begin{aligned} A_1 : \quad \frac{d}{\delta} &= \frac{3}{2} \frac{\delta}{b} , \\ B_1 : \quad \frac{d}{\delta} &= \frac{1}{4} \frac{\epsilon_1}{\epsilon_0} k_o \delta k_o b . \end{aligned} \quad (42)$$

Both are extremely small. As an example, consider the case  $\epsilon_1 = 4\epsilon_0$  and  $k_o b = 0.2$ . For a typical metal at microwave frequencies,  $k_o \delta = 10^{-5}$  (a value achieved by pure drawn gold at a frequency 37 MHz), giving

$$A_1 : \quad \frac{d}{\delta} = 7.5 \times 10^{-5}$$

$$B_1 : \quad \frac{d}{\delta} = 0.2 \times 10^{-5}$$

As  $d$  is decreased, the coefficient  $A_1$  first departs from its value for a metallic sphere and, in our example, goes over completely to its value for a dielectric sphere before the transition for  $B_1$  occurs. This last is centered on  $0.2 \times 10^{-5}$  and is not completed until  $d/\delta$  is (say) a factor 5 smaller still. To appreciate how thin such layers are, we remark that for gold at a frequency of 37 MHz,  $\delta = 1.3 \times 10^{-5}$  m. Thus, for  $B_1$ , the transition is centered on a layer thickness  $d$  of only  $0.26 \text{ \AA}^0$  ( $1 \text{ \AA}^0 = 10^{-8}$  cm.), and since this is comparable (or

less than) the dimensions of a molecule, Maxwell's theory cannot be presumed to hold. Certainly it is difficult to conceive of such a "uniform" layer being deposited.

Changing  $\frac{\epsilon_1}{\epsilon_0}$ , the conductivity of the metal used or the frequency of illumination does not drastically affect these conclusions. As  $b$  is increased, the transitional values for  $A_1$  and  $B_1$  approach one another and though this would, in the above example, violate the criterion for Rayleigh scattering, the first order modes will continue to be significant contributors to the scattering for all  $k_0 b \leq 2$ . Though they will not be the only contributors for  $k_0 b \gg 0.2$ , this argument suggests that even for  $k_0 b$  as large as 2 the transition between the metallic and dielectric sphere behaviors will still occur for layer thickness in the  $0.1$  to  $10 \text{ \AA}^0$  range. A simple requirement for substantial penetration of energy through the layer, e.g.  $d < \delta$ , is therefore irrelevant to the retention of the dielectric sphere behavior.

### Computer Program

For the specific problem of concern to us

$$\mu_1 = \mu_2 = \mu_0 ,$$

$$\epsilon_1 \text{ is real}$$

and

$$\epsilon_2 = \epsilon_0 + i\epsilon_2'' \quad (43)$$

with

$$\epsilon_2'' = \frac{\sigma}{\omega} \quad (44)$$

where  $\sigma$  is the conductivity (in mhos/m.) of the layer material. For a metal,

$\sigma$  is of order  $10^7$  and the corresponding penetration depth is

$$\delta = \frac{1}{k_0} \sqrt{\frac{2\epsilon_0}{\epsilon_2''}} , \quad (45)$$

which is of order  $10^{-5}$  m. at 50 MHz. The complex propagation constant in the metal layer is then

$$k_2 = k_0 \sqrt{1 + i \frac{2}{(k_0 \delta)^2}} \quad (46)$$

and whilst this is the formula used to compute  $k_2$  in the program, an approximation which is adequate for all practical purposes is

$$k_2 = \frac{1+i}{\delta} . \quad (47)$$

For the above choice of permeabilities, the expressions (19) and (20) for the modal impedance factors become

$$\Gamma_n^{(1)} = \frac{k_0}{k_2} \frac{\psi_n(k_1 a) \cos k_2 d + k_1/k_2 \psi'_n(k_1 a) \sin k_2 d}{\psi_n(k_1 a) \sin k_2 d - k_1/k_2 \psi'_n(k_1 a) \cos k_2 d} \quad (48)$$

$$\Gamma_n^{(2)} = \frac{k_0}{k_2} \frac{\psi'_n(k_1 a) \cos k_2 d - k_1/k_2 \psi_n(k_1 a) \sin k_2 d}{\psi'_n(k_1 a) \sin k_2 d + k_1/k_2 \psi_n(k_1 a) \cos k_2 d} \quad (49)$$

compared with which the surface impedance factor is

$$\Gamma = \frac{k_0}{k_2} \cot k_2 d . \quad (50)$$

The computer program is written in Fortran IV and uses in a straightforward

manner the expressions (48) and (49) in association with eqs. (2) through (5). Double precision is employed throughout to ensure that the wide variations in some of the factors will not introduce significant errors. The modified Bessel and Hankel functions  $\psi_n(z)$  and  $\xi_n(z)$  are calculated via backward and forward recursion schemes respectively using a Radiation Laboratory subroutine developed for functions with complex arguments. In eqs. (2) and (3), the infinite series for  $S(0)$  and  $S(\pi)$  are truncated at the 15th term. Thus,  $n \leq 15$  and though this limits the spheres that can be handled to those for which  $k_1 b \lesssim 6$ , the limitation can be easily overcome by increasing the array sizes and NMAX.

The input data specifies the choice of parameters and also selects from several options on the composition of the output. The propagation constant  $k_o^{(KO)}$  is measured in  $\text{m.}^{-1}$  and specifies the frequency of the incident illumination via  $k_o = \omega/c$  where  $\omega$  is the circular frequency ( $= 2\pi f$ ) and  $c$  is the velocity of light in free space. The sphere is specified by its outer radius  $b$  (BL) and the layer thickness  $d$  (D1); the difference is the radius  $a$  (AL) of the inner. All dimensions are in meters. The dielectric constant of the metal coating is defined in eq. (43) and is therefore specified completely by the ratio  $\epsilon_2''/\epsilon_0^{(E2OEO)}$ . The dielectric constant of the dielectric sphere is likewise specified by the ratio  $\epsilon_1/\epsilon_0^{(E1OEO)}$ .

The values assigned to I1, I2 determine the form of the output. The non-optional part of this includes:

- (i) all the input parameters
- (ii) the penetration depth  $\delta$  in the metal (see eq. 45)
- (iii) the propagation constants
- and (iv) the far field amplitudes  $S(0)$ ,  $S(\pi)$  in real and imaginary parts, plus normalised cross sections  $\frac{\sigma(0)}{\pi a^2}$ ,  $\frac{\sigma(\pi)}{\pi a^2}$  and the phases  $\arg S(0)$ ,

$\arg S(\pi)$  in degrees, for the coated sphere and an uncoated one (quantities denoted by an asterisk) of the same size.

If  $I_1 \neq 0$  (or blank),  $\Gamma_n^{(1)}$  and  $\Gamma_n^{(2)}$  are printed for both the coated and uncoated spheres, along with the surface impedance factor  $\Gamma$  (see eq. 50). This is useful for seeing how the individual modes are differentially affected.

If  $I_2 \neq 0$  (or blank), the coefficients  $A_n$  and  $B_n$  are printed for both the coated and uncoated spheres. This enables the individual modal contributions to be examined, as well as the adequacy of the truncation at the 15 th term.

Input data:

card 1	$k_o$	KO	(F 12.5)
card 2	b	BL	(F 20.12)
card 3	d	D1	(F 20.12)
card 4	$\epsilon_1/\epsilon_o$	E1OEO	(F 20.12)
card 5	$\epsilon_2/\epsilon_o$	E2OEO	(F 20.5)
card 6	$I_1, I_2$		(2I2)

A program listing is included in the Appendix along with the output from a typical run.

### Computations

Some of the data that have been obtained for the normalised back and forward scattering cross sections  $\frac{\sigma(0)}{\pi a^2}$  and  $\frac{\sigma(\pi)}{\pi a^2}$  are shown in Figs. 2 through 7. In all cases the coating material is pure drawn gold whose microwave conductivity is  $4.1 \times 10^7$  mhos/m. (Stratton, 1941; p. 605). The frequency has been taken to be 47.7465 MHz for which  $k_o = 1 \text{ m.}^{-1}$  and  $\delta = 1.136 \times 10^{-5} \text{ m.}$ , and the curves are drawn from the sampled values  $k_o b = 0.2 / (0.2) 2.0$  for a variety of coating thick-

nesses.

In Figs. 2 through 5,  $\epsilon_1 = 4\epsilon_0$ . Results have been obtained for coating thicknesses from  $10^{-5}$  m. ( $= 0.8803 \delta$ ) down, but it is not until  $d$  has been reduced to about  $10^{-9}$  m. ( $= 10 \text{ \AA}^0$ ) that any significant departures from the metallic sphere behavior are observed. The curves in Figs. 2 through 5 are for  $d = 10, 5, 1, 0.75, 0.5, 0.25$  and  $0.1 \text{ \AA}^0$  and in each Figure the curves for a metallic and the dielectric (uncoated) sphere are included for comparison. As regards the backscattering cross section, the first thickness of coating to display any indication of the deep minimum\* at  $k_0 b \approx 1.36$  is  $0.25 \text{ \AA}^0$ , and it is necessary to go down to  $0.1 \text{ \AA}^0$  to reproduce the minimum with any accuracy. Even then there are still large differences from the curve for the uncoated sphere for  $k_0 b > 1.5$ . In the forward direction [the curves are more regular with no pronounced minima, but even so the curve for the thinnest coating ( $d = 0.1 \text{ \AA}^0$ ) still departs noticeably from the dielectric one for  $k_0 b$  in the vicinity of 1.5.]

The effect of a change in the permittivity is illustrated in Figs. 6 and 7 where we have taken  $\epsilon_1 = 3.5 \epsilon_0$  and reproduced only the curves for the single coating thickness  $d = 0.5 \text{ \AA}^0$ . The departures from the dielectric sphere behavior are quite significant.

The obvious conclusion that can be drawn is that if we are to retain the dielectric sphere behavior in the presence of a metallic coating, the coating thickness must be extremely small ( $\sim 10^{-6} \delta$ ). For small spheres in the Rayleigh region this same conclusion was previously arrived at analytically, and it is not hard to see why it is also valid for larger spheres.

Given a plane wave in free space incident normally on a slab of material

\* This minimum is undoubtedly a consequence of the single-bounce (glory ray) contribution; see, for example, Peters, 1969.

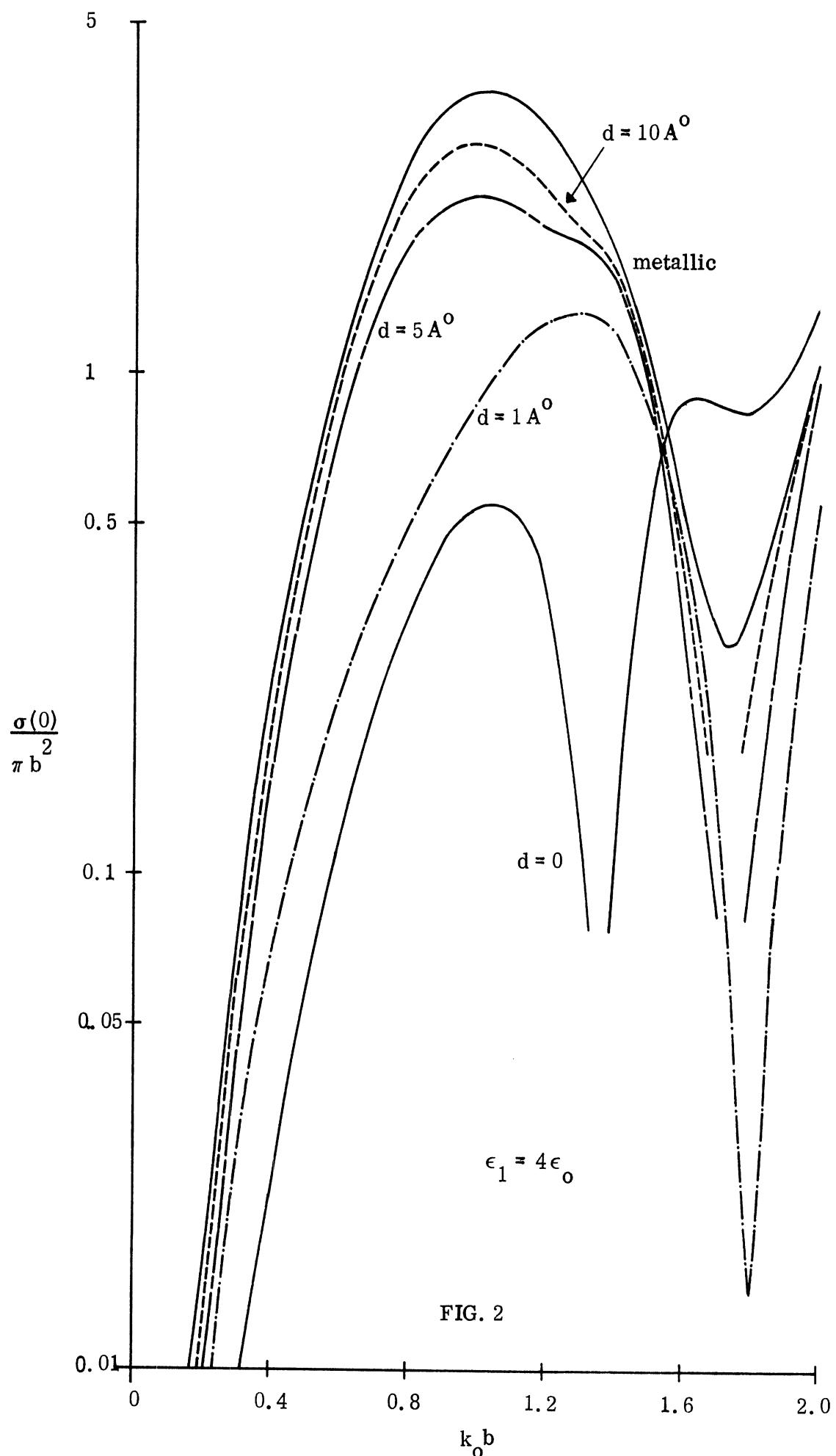
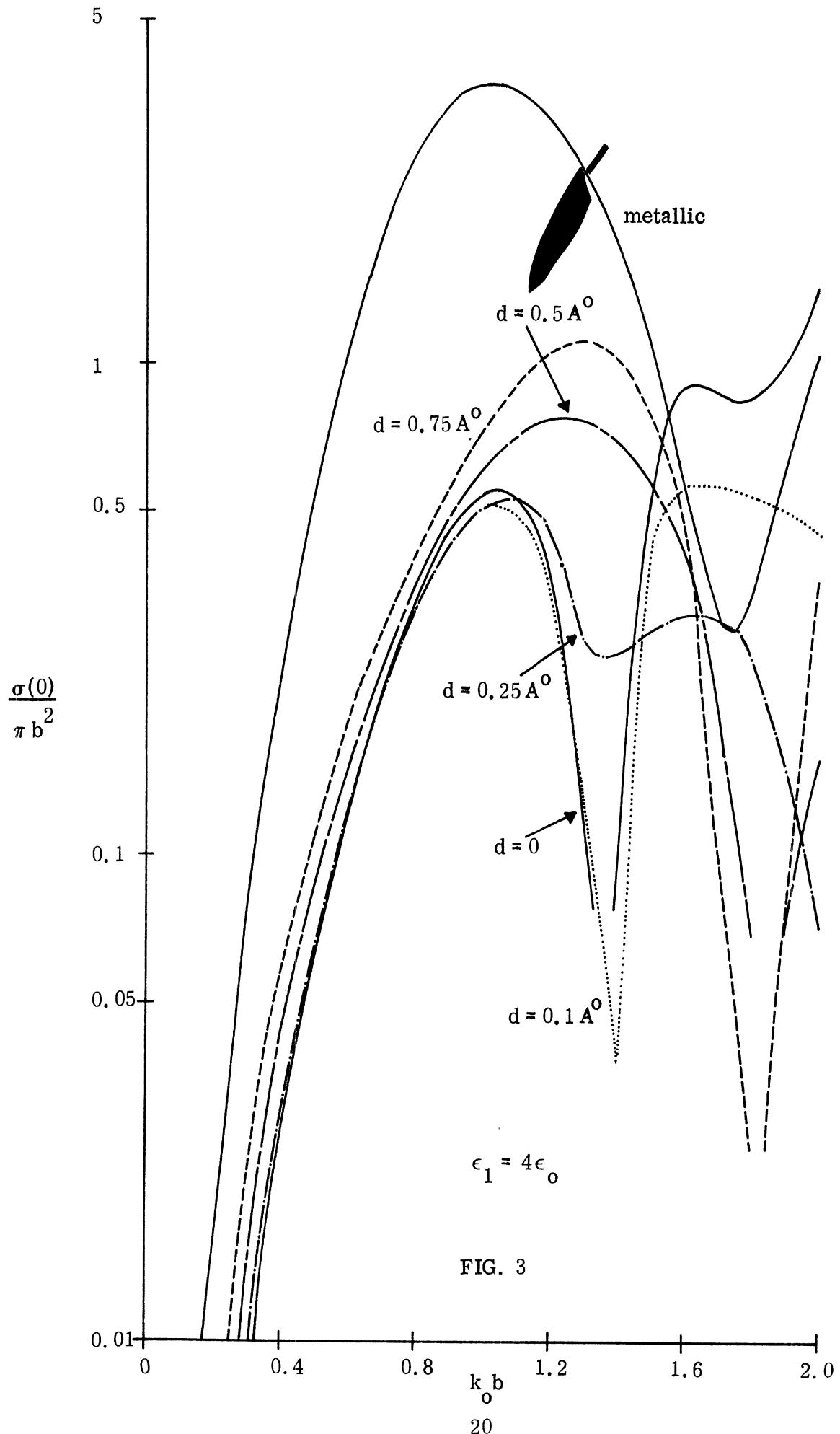
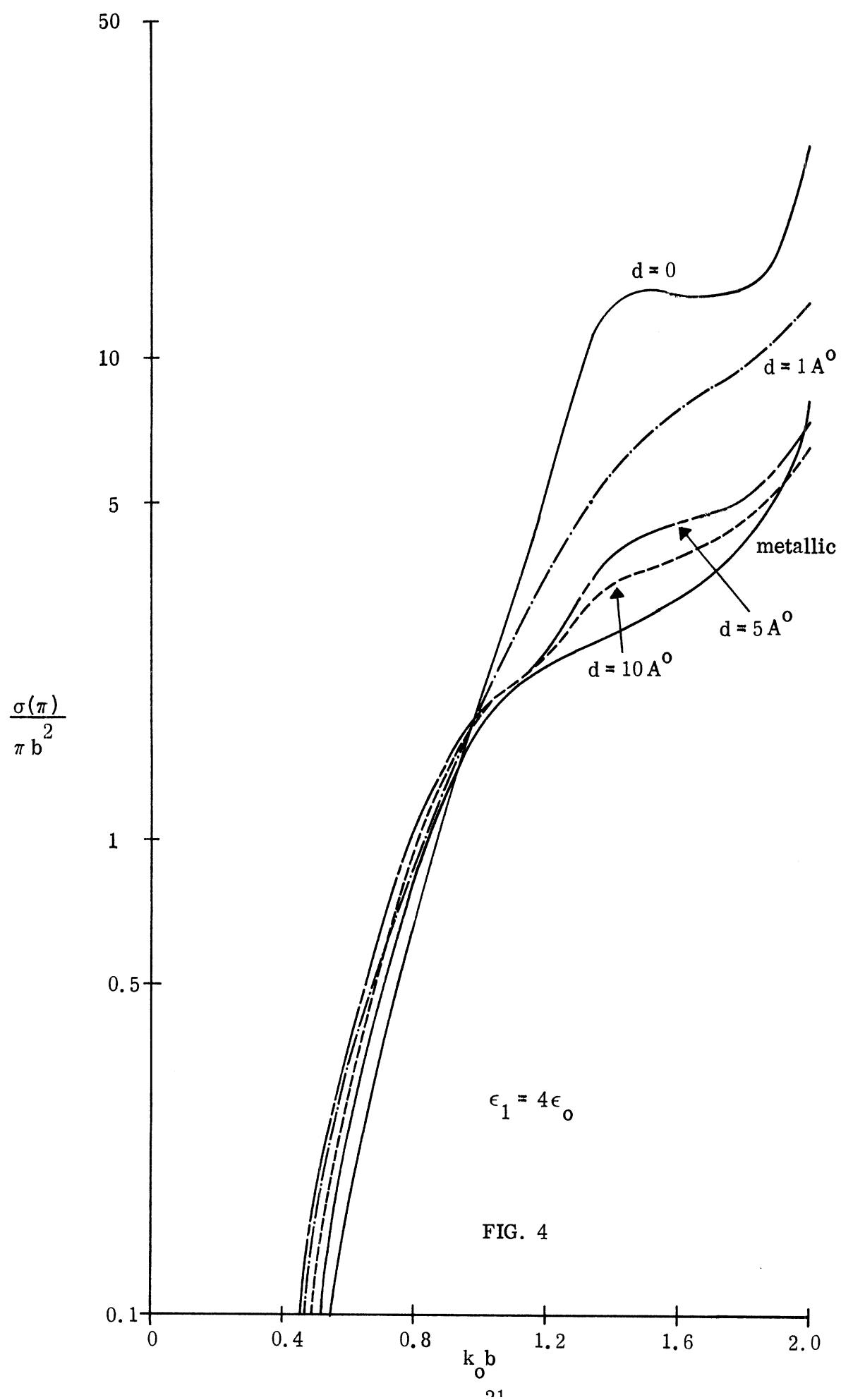
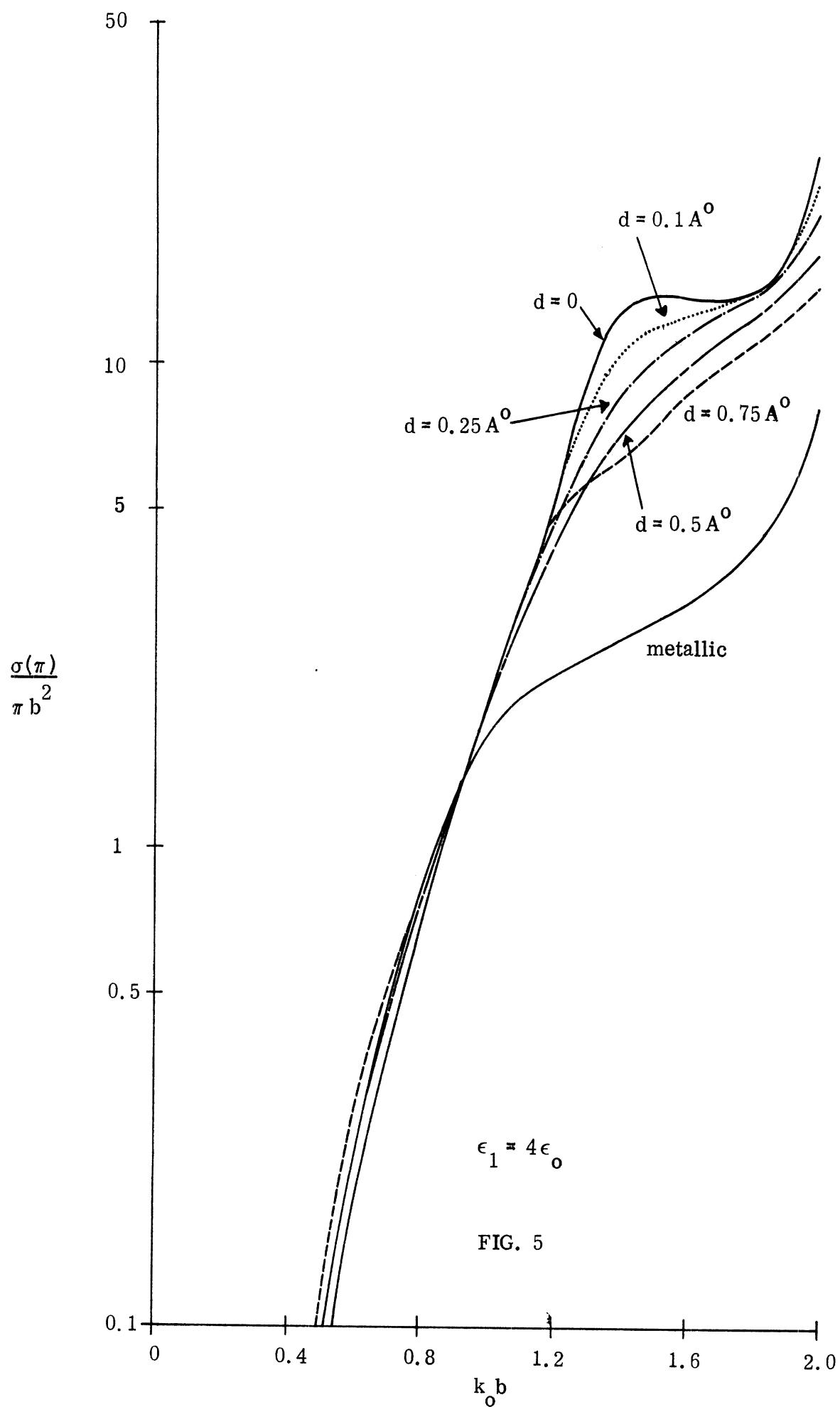
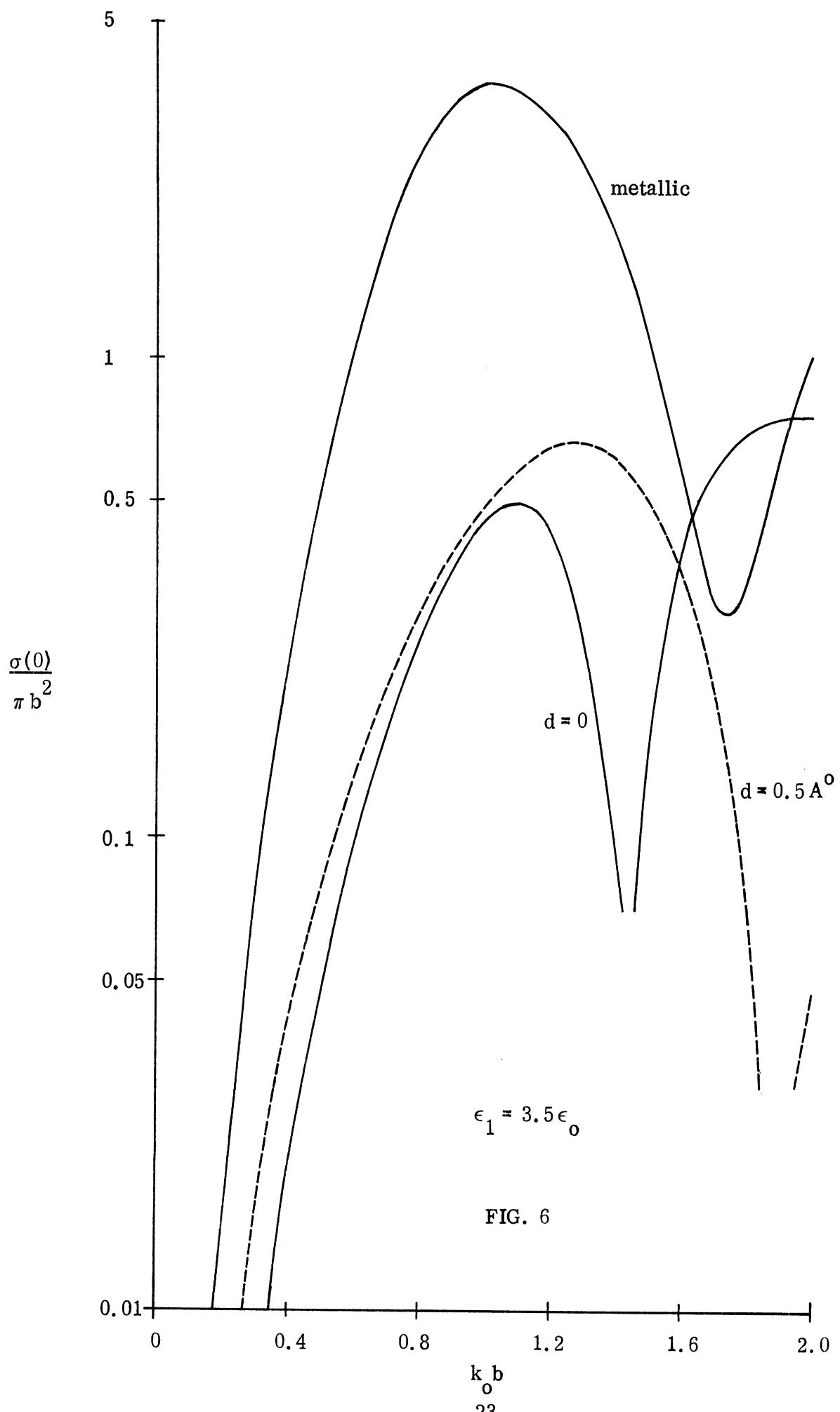


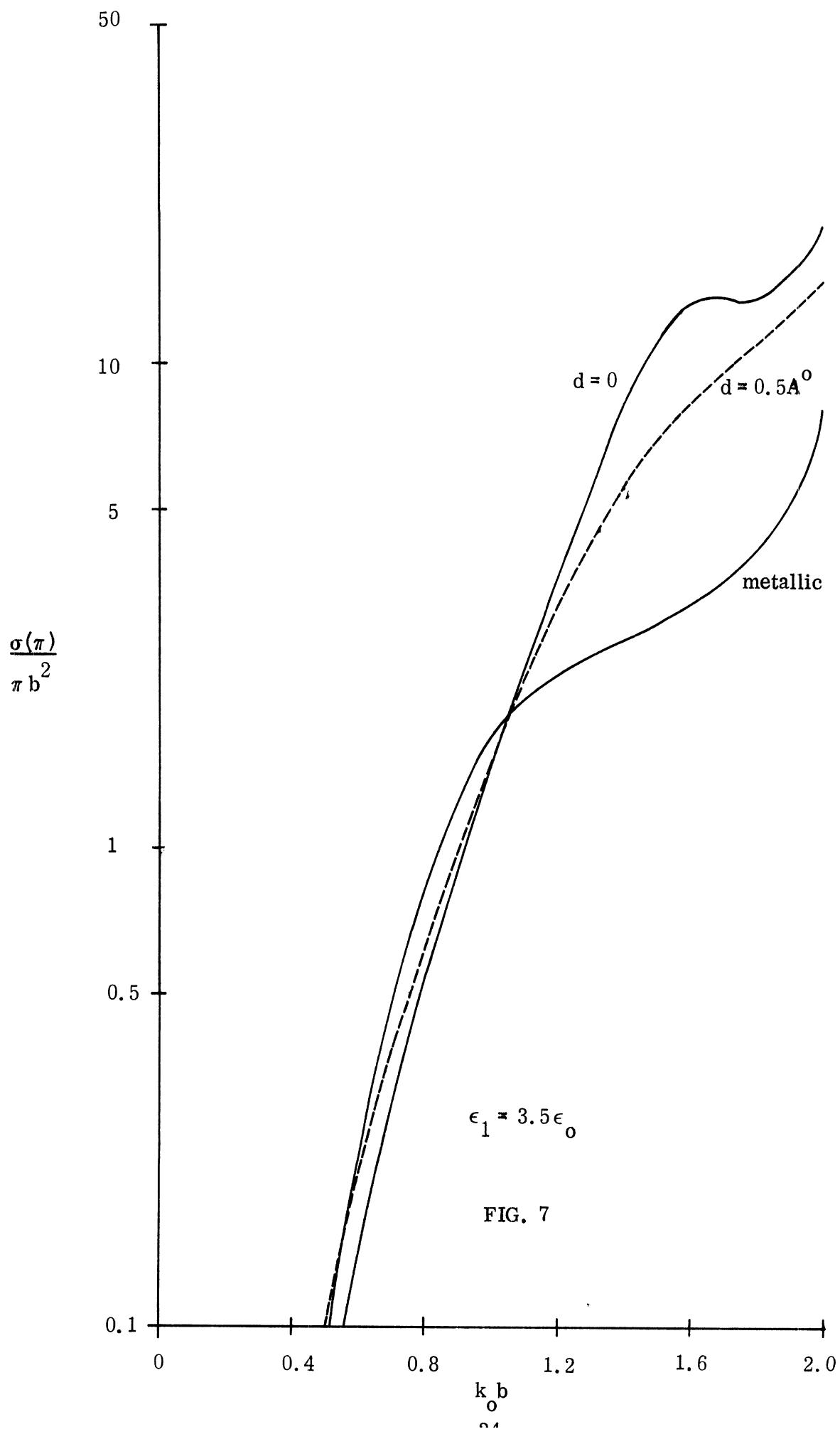
FIG. 2











having  $\epsilon = \epsilon_2$ ,  $\mu = \mu_2$  and thickness  $d$ , and backed by infinitely extended material having  $\epsilon = \epsilon_1$ ,  $\mu = \mu_1$ , the magnitude of the transmission coefficient is

$$T = \frac{2}{\left| \left( 1 + \frac{Z_1}{Z_o} \right) \cos k_2 d - i \left( \frac{Z_2}{Z_o} + \frac{Z_1}{Z_2} \right) \sin k_2 d \right|}. \quad (51)$$

If the slab material is metallic and  $k_2 d \ll 1$ , eq. (51) reduces to

$$T \approx 2 \left\{ 1 + \sqrt{\frac{\epsilon_o}{\epsilon_1}} \left( 1 + 2 \frac{d/\delta}{k_o \delta} \right) \right\}^{-1}$$

where we have put  $\mu_1 = \mu_2 = \mu_o$ , and for this to exceed (say) 50 percent, the requirement is

$$\frac{d}{\delta} < \frac{k_o \delta}{2} \left( 3 \sqrt{\frac{\epsilon_1}{\epsilon_o}} - 1 \right). \quad (52)$$

The right hand side is of order  $10^{-5}$  at 50 MHz, which again implies a layer thickness comparable to  $1 \text{ \AA}^0$ . In other words, the extreme mismatch at the surface of the metal for all except the most infinitesimal thicknesses prevents any penetration through.

REFERENCES

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- Goodrich, R. F., B. A. Harrison, R. E. Kleinman and T. B. A. Senior (1961), Studies in radar cross sections XLVII, The University of Michigan Radiation Laboratory Report No. 3648-1-T.
- Peters, L., Jr. (1969), Modified geometrical optics for dielectric scattering: Short course "Application of optical methods to microwave problems," The Ohio State University.
- Scharfman, H. (1954), Scattering from dielectric coated spheres in the region of the first resonance, *J. Appl. Phys.* 25, 1352-1356.
- Stratton, J. A. (1941), Electromagnetic theory, McGraw-Hill Book Company, Inc., New York.

## Appendix

### Computer Program

```
CC01      C COMPUTE 16 ABFS(2,15), ADHFS(2,15), AHANK(2,15), ADHANK(2,15),
          C THF A---- ARRAYS JUST STORE THF CNPR FSPONDING
          C SPHERICAL BESSFL FUNCTIONS.
          I0UT(4,15)

CC02      C COMPLEX*16 BFS(17),HANK(17),DHANK(17)
          C COMPLEX*16 MULT,A,R,C,D,X,KR,KNK1,KNK2,S1,S2,S3,S4,KD
          C REAL*8 A,B,KD,KB,AL,RL,E10EN,E20EN,D1,DELT,T
          C REAL*8 SIG1,SIG2,SIG3,SIG4,DRFAL,DIMAG
          C REAL*8 P1,P2,P3,P4,R1,R2,R3,R4
          C MULT(A,R,C,D)=A*R-C*D
          C TAKES THE REAL PART.
          DREAL(A)=(A+DCONJG(A))/2.00
          C TAKES THE IMAGINARY PART.
          DIMAG(A)=(C*0,-1.0)*(A-DCONJG(A))/2.00
          CPIE=3.1415962
          C TO INCREASE THE NUMBER OF MODES TO BE CALCULATED
          C NMAX MUST BE INCREASED AS WELL AS ALL ARRAYS.
          NMAX=16
          C THE INPUT IS READ IN AS FOLLOWS;KD/BL/D1/E10EO/E20EO/I1,I2
          C READ(5,1) KD
          KC IS THE FREE-SPACE PROPAGATION CONSTANT.
          C 1 FORMAT(F12.5)
          C READ(5,1) BL
          BL IS THE RADIUS OF THE OUTER SPHERE.
          C READ(5,61) D1
          C READ(5,61) E10EO
          E10EO IS THE RELATIVE DIELECTRIC CONSTANT OF
          THE INNER SPHERE.
          C 61 FORMAT(F20.12)
          C READ(5,62) E20EO
          E20EO IS THE IMAGINARY PART OF THE DIELECTRIC
          C CONSTANT OF THE METAL COATING.
          C 62 FORMAT(F20.5)
          C READ(5,40) I1,I2
          C 40 FORMAT(2I1)
```

```

CC23
CC24      WRITE(6,2) AL
CC25      2 FORMAT('1', 'THE RADIUS OF THE INNER SPHERE IS', *
CC26      1F2C•12,2X,'METERS')
CC27      WRITE(6,3) BL
CC28      3 FORMAT(' ', 'THE RADIUS OF THE OUTER SPHERE IS', *
CC29      1F2C•8,2X,'METERS')
CC30      4 FORMAT(' ', 'THE THICKNESS OF THE CATING IS', *
CC31      1D20•8,2X,'METERS')
CC32      C      PENETRATION DEPTH CALCULATIONS*
CC33      DELT=DSQRT(2•DC/(K0*K0*E20EN))
CC34      WRITE(6,5) DELT
CC35      5 FORMAT(' ', 'THE PENETRATION DEPTH IS', ,D15•7,2X,'METERS')
CC36      T=D1/DELT
CC37      WRITE(6,6) T
CC38      6 FORMAT(' ', 'THE CATING THICKNESS IS', ,D15•7,2X,'TIMES
CC39      1 THE PENETRATION DEPTH')
CC40      K0B=K0*BL
CC41      WRITE(6,7) K0B
CC42      7 FORMAT(' ', 'K0B IS', ,F15•7)
CC43      KB=DCMPY(K0B,G,DC)
CC44      ADR=AL/RL
CC45      T=1•CC00/DSQRT(F10FC)
CC46      C      THE RELATIVE PROPAGATION CONSTANTS ARE DETERMINED.
CC47      K0K1=DCMPLEX(T,A,DC)
CC48      K0K2=DCMPLEX(1•DC,E20EN)
CC49      K0K2=1•CC00/DSQRT(K0K2)
CC50      X=KB
CC51      WRITE(6,71) F20E0
CC52      71 FORMAT(' ', 'F2/E0 IS', ,2X,D15•7)
CC53      WRITE(6,72) E10FC
CC54      72 FORMAT(' ', 'E1/E0 IS', ,2X,D15•7)
CC55      WRITE(6,73) KCK1
CC56      73 FORMAT(' ', 'K0/K1 IS', ,2(2X,D15•7))
CC57      WRITE(6,74) K0K2
CC58      74 FORMAT(' ', 'K0/K2 IS', ,2X,D15•7,2X,D15•7)

```

```

0054      C      CALL CRFS(DRES,HANK,DHANK,X,NMAX)
          C      THE SPHERICAL BESSSEL FUNCTIONS FOR ARGUMENT KOB
          C      ARE CALCULATED.
          DD 9  I=2,NMAX
          ARFS(1,I)=BES(I)
          DRES(1,I)=DRES(I)
          AHANK(1,I)=HANK(I)
          8  ADHANK(1,I)=DHANK(I)
          C      THE SPHERICAL BESSSEL FUNCTIONS FOR ARGUMENT KIA
          C      ARE CALCULATED.
          X=KB*ANB/KOK1
          CALL CRFS(BES,DRES,HANK,DHANK,X,NMAX)
          DD 1  I=2,NMAX
          ABFS(4,I)=BES(I)
          ABFS(4,I)=DRES(I)
          AHANK(4,I)=HANK(I)
          AHANK(4,I)=DHANK(I)
          11  ADHANK(4,I)=DHANK(I)
          C      THE SPHERICAL BESSSEL FUNCTIONS FOR ARGUMENT KIB
          C      ARE CALCULATED.
          X=X/ANB
          CALL CRFS(BES,DRES,HANK,DHANK,X,NMAX)
          A=QC'MPLX(1.000E20E0)
          K2D IS CALCULATED.
          A=D1*D1*A
          B=CDSORT(A)
          KD=K0*B
          WRITE(6,101) KD
          101  FORMATT(•,•,K2D TS •,D20.12,2X,D2C•112)
          A=CCOS(KD)
          R=-CCSIN(KD)/(KB*ANB/KOK2)
          C=(KB/KOK2)*CCSIN(KD)
          D=CCOS(KD)/ANB
          AI=A
          BI=B*(KOK1/KOK2)*(KOK1/KOK2)
          CI=KOK2*KCK2*C
          DI=KOK1*KCK1*D

```

```

CC93      DO 12 J=2,NMAX
          AHANK(4,J)=MULT(ABES(4,J),A,ADRES(4,J),R)
          AHANK(4,J)=AHANK(4,J)/(MULT(ABES(4,J),C,ADRES(4,J),R))
          C      PROPORTIONAL TO GAMMA-1.
          AHANK(4,J)=MULT(ABES(4,J),AI,ADRES(4,J),RI)
          AHANK(4,J)=ADHANK(4,J)/(MULT(ABES(4,J),CI,ADRES(4,J),DI))
          C      PROPORTIONAL TO GAMMA-2.
          OUT(1,J)=ABES(1,J)+ADRES(1,J)*AHANK(4,J)
          OUT(1,J)=OUT(1,J)/(AHANK(1,J)+ADHANK(1,J)*AHANK(4,J))
          AN=OUT(1,N).
          OUT(2,J)=ABES(1,J)+ADRES(1,J)*ADHANK(4,J)
          OUT(2,J)=OUT(2,J)/(AHANK(1,J)+ADHANK(1,J)*ADHANK(4,J))
          RN=OUT(2,N).
          HANK(J)=RES(J)/RES(J)
          C      *-ED QUANTITIES REFER TO THE DIELECTRIC SPHERE.
          C      PROPORTIONAL TO GAMMA-1*.
          DHANK(J)=HANK(J)/(K0K1*K0K1)
          PROPORTIONAL TO GAMMA-2*.
          OUT(3,J)=ABES(1,J)+ADRES(1,J)*HANK(J)
          OUT(3,J)=OUT(3,J)/(AHANK(1,J)+ADHANK(1,J)*HANK(J))
          AN*=OUT(3,N).
          OUT(4,J)=ABES(1,J)+ADRES(1,J)*DHANK(J)
          OUT(4,J)=OUT(4,J)/(AHANK(1,J)+ADHANK(1,J)*DHANK(J))
          RN*=OUT(4,N).
          C      12 CONTINUE
          C      OPTIONAL OUTPUT RELATED TO 11.
          IF(11.EQ.0) GO TO 16
          WRITE(6,13)
          13 FORMAT(' ',15X,' ORDER ',23X,' GAMMA-1',23X,' GAMMA-2')
          DO 15 K=2,NMAX
          L=K-1
          AHANK(4,K)=K*R*AHANK(4,K)
          ADHANK(4,K)=-1.000/(KB*ADHANK(4,K))
          WRITE(6,14) L,AHANK(4,K)*ADHANK(4,K)
          14 FORMAT(' ',15X,I5,4(5X,D15.7))
          15 CONTINUE

```

```

C109      WRITE(5,32)
C110      30  FORMAT(' ',15X,'ORDER',22X,'GAMMA-1*',22X,'GAMMA-2**')
C111      DD 31  K=2,NMAX
C112      C112
C113      L=K-1
C114      HANK(K)=KR*HANK(K)
C115      DHANK(K)=-1.00/(KR*DHANK(K))
C116      WRITE(6,32) L,HANK(K),DHANK(K)
C117      32  FORMAT(' ',15X,15,4(5X,D15.7))
C118      CONTINUE
C119      IF(D1.EQ.0.0) GO TO 16
C120      X=K0K2*C0C0S(KD)/C0SIN(KD)
C121      WRITE(6,83) X
C122      83  FORMAT(' ',THE IMPEDANCE OF THE SURFACE LAYER IS',
C123      12X,D15.7,2X,D15.7)
C124      S1=0.00000
C125      S2=0.00000
C126      S3=0.00000
C127      S4=0.00000
C128      DD 17  M=2,NMAX
C129      K=M-1
C130      H=K
C131      S1=(-1)**K*(H+5.0)*((OUT(1,M)-OUT(2,M))+S1)
C132      S2=(H+5.0)*(OUT(1,M)+OUT(2,M))+S2
C133      S3=(-1)**K*(H+5.0)*((OUT(3,M)-OUT(4,M))+S3)
C134      S4=(H+5.0)*(OUT(3,M)+OUT(4,M))+S4
C135      C135
C136      C136
C137      C137
C138      C138
C139      C139
C140      C140
C141      41  FORMAT(' ',S(0) IS*,D20.8,5X,D20.8)
C142      WRITE(6,42) S2
C143      42  FORMAT(' ',S(PIF) IS*,D20.8,5X,D20.8)
C144      WRITE(6,43) S3
C145      43  FORMAT(' ',S(0)*IS*,D20.8,5X,D20.8)
C146      WRITE(6,44) S4
C147      44  FORMAT(' ',S(PIF)*IS*,D20.8,2X,D20.8)

```

```

C146 SIG1=S1*DCONJG(S1)/(K0B/2.000)**2
C147 P1=DRFAL(S1)
C148 P1=DIMAG(S1)
C149 P1=DATAN2(R1,P1)
C150 P1=P1*180.0/PIE
C151 SIG2=S2*DCONJG(S2)/(K0B/2.000)**2
C152 P2=DRFAL(S2)
C153 R2=DIMAG(S2)
C154 P2=DATAN2(R2,P2)
C155 P2=P2*180.0/PIE
C156 SIG3=S3*DCONJG(S3)/(K0B/2.000)**2
C157 P3=DREAL(S3)
C158 P3=DIMAG(S3)
C159 P3=DATAN2(R3,P3)
C160 P3=P3*180.0/PIE
C161 SIG4=S4*DCONJG(S4)/(K0B/2.000)**2
C162 P4=DREAL(S4)
C163 R4=DATAN2(R4,P4)
C164 P4=P4*180.0/PIE
C165 C      N IS THE NORMALIZATION FACTOR
C166 WRITE(6,45) SIG1,P1
C167 45 FORMAT(' ',SIGMA(C)/N IS ',F15.7
C168   1,2X,' ,PHI IS ',F15.7,2X,' DEGREES')
C169   WRITE(6,46) SIG2,P2
C170 46 FORMAT(' ',SIGMA(PIE)/N IS ',F15.7
C171   1,2X,' ,PHI IS ',F15.7,2X,' DEGREES')
C172   WRITE(6,47) SIG3,P3
C173 47 FORMAT(' ',SIGMA(0)*N IS ',F15.7
C174   1,2X,' ,PHI IS ',F15.7,2X,' DEGREES')
C175   WRITE(6,48) SIG4,P4
C176 48 FORMAT(' ',SIGMA(PIE)*N IS ',F15.7
C177   1,2X,' ,PHI IS ',F15.7,2X,' DEGREES')

```

```
C      OPTIONAL OUTPUT RELATED TO I2.  
C174      IF(I2,F0,Q) GO TO 100  
C175      WRITE(6,25)  
C176      FORMAT(1,10X,'SPHERE WITH LAYER',26X,',DIELECTRIC SPHERE')  
C177      DO 103 JJ=2,NMAX  
C178      WRITE(6,102) OUT(1,JJ),OUT(2,JJ),OUT(3,JJ),OUT(4,JJ)  
C179      102 FORMAT(1,8D13.5)  
C180      103 CONTINUE  
C181      102 CONTINUE  
C182      STOP  
C183      END
```

```

C      C BES CALCULATES THE SPHERICAL BESSEL FUNCTIONS
C      UP TO ORDER NMAX WITH ARGUMENT X.
C      SUBROUTINE BES(NMAX,X,BES,HANK,DHANK,X,NMAX)
C      COMPLEX*16 ZFS(17),DBES(17),HANK(17),DHANK(17),I
C      COMPLEX*16 X,JN,J(99),P,Y(75)
C      INDX IS ONE GREATER THAN ORDER.
C      BES(N+1)=JN(X),DBES(N+1)=(XJN(X))",
C      HANK(N+1)=HN(X),DHANK(N+1)=(XHN(X)),
C      I=(0,0,1,0)
C      NMAX=NMAX+16
C      NQ=N-N-1
C      NP=N-N-2
C      NQ=NMAX+1
C      NP=NMAX+2
C      J(NN)=(0.00,0.00)
C      J(NQ)=(1.00,1.00)
C      JN=CD SIN(X)/X
C      Y(1)=-CD COS(X)/X
C      Y(2)=Y(1)/X-JN
C      DO 10 M=1,NP
C      N=NQ-N
C      10  J(N)=(2*(N-1)+3)*J(N+1)/X-J(N+2)
C      DO 12 N=3,NR
C      12  Y(N)=((2*(N-1)-1)/X)**Y(N-1)-Y(N-2)
C      P=JQ/J(1)
C      RES(1)=J(1)**P
C      HANK(1)=BES(1)+I*Y(1)
C      DO 20 L=1,NQ
C      K=L+1
C      BES(K)=J(K)**P
C      HANK(K)=BES(K)+I*Y(K)
C      DBES(L)=L*BES(L)-X*BES(K)
C      DHANK(L)=L*HANK(L)-X*HANK(K)
C      CONTINUE
C      RETURN
C      END
CC01
CC02
CC03
CC04
CC05
CC06
CC07
CC08
CC09
CC10
CC11
CC12
CC13
CC14
CC15
CC16
CC17
CC18
CC19
CC20
CC21
CC22
CC23
CC24
CC25
CC26
CC27
CC28
CC29
CC30

```

Sample Output

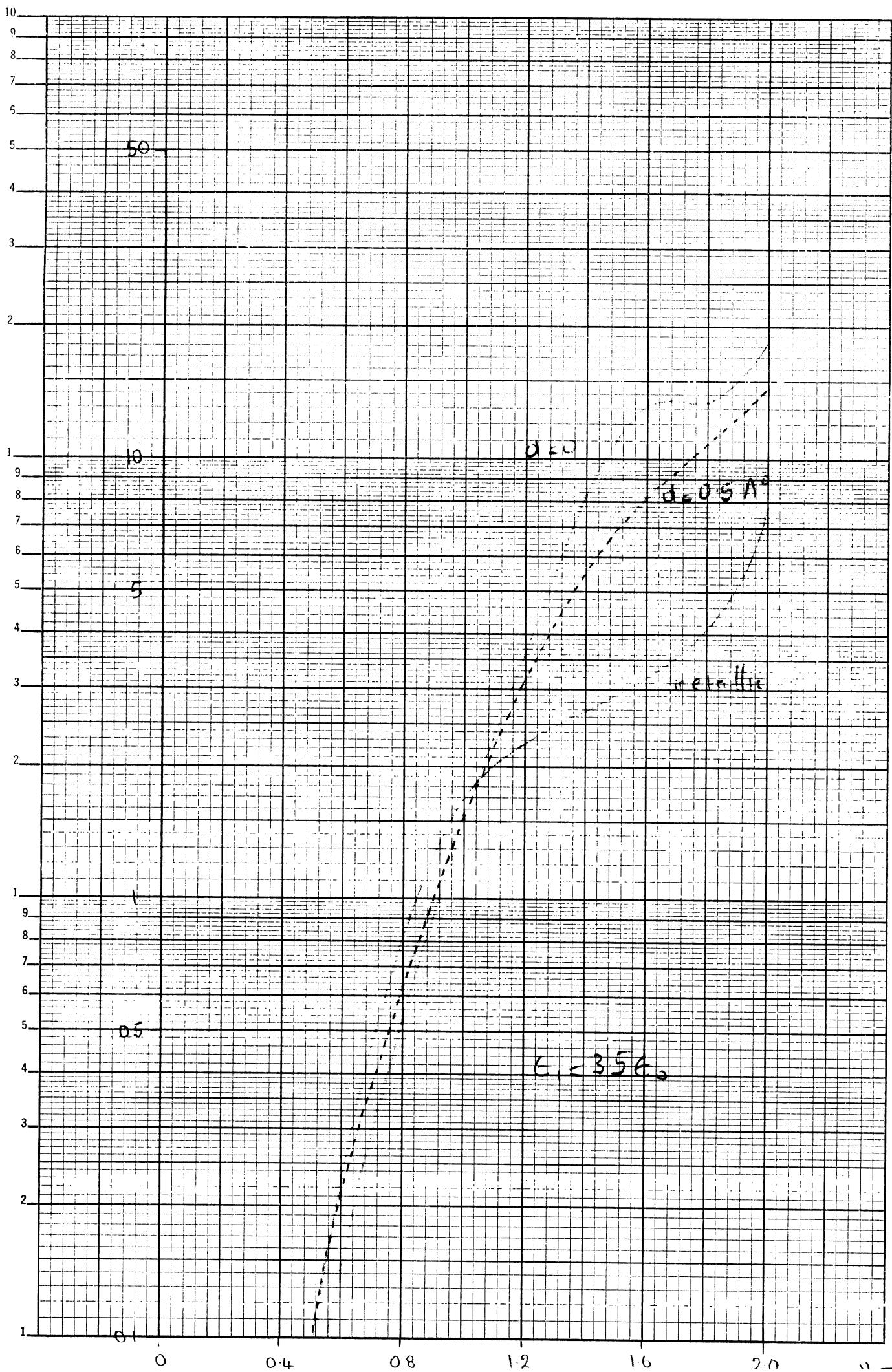
THE RADIUS OF THE INNER SPHERE IS 0.999999999999 METERS  
THE RADIUS OF THE OUTER SPHERE IS 1.000000000000 METERS  
THE THICKNESS OF THE COATING IS 0.100000000000 METERS  
THE PENETRATION DEPTH IS 0.1135924D-04 METERS  
THE COATING THICKNESS IS 0.98C34C9D-04 TIMES  
KOR IS 1.000000000000  
E2/FC IS 0.155000000000 D 11  
F1/FC IS 0.400000000000 01  
KC/K1 IS 0.500000000000 00  
KC/K2 IS 0.5679619D-05 -0.5679618D-05  
K2D IS 0.880340843111D-04 C.880340843055D-04

ORDER	GAMMA-1	GAMMA-2
1	-0.4508173D-02	-0.6419956D-01
2	-C.97C93C7D-02	-0.632225D-01
3	-0.1399Cf3D-01	-0.68915139D-02
4	-0.1767906D-01	-0.6132416D-01
5	-C.2C85921D-01	-0.5924C16D-01
6	-0.2356682D-01	-0.54285C5D-01
7	-0.2582985D-01	-0.5153166D-01
8	-0.2767948D-01	-0.4382396D-01
9	-0.2915161D-01	-0.460989D-01
10	-0.3028546D-01	-0.4336542D-01
11	-0.3112156D-01	-0.427452CD-01
12	-0.3169574D-01	-0.382328CD-01
13	-0.3205776D-01	-C.3594728D-01
14	-0.3223036D-01	-0.3259483D-01
15	-0.3224869D-01	-0.3149023D-01
ORDER	GAMMA-1*	GAMMA-2*
1	-C.9187552D CC	0.0
2	-C.4187552D CC	0.0
3	-C.282784CD CC	0.0
4	-C.2161349D CC	0.0
5	-0.1758781D CC	0.0
6	-C.1486C99D CC	0.0
7	-0.1288373D CC	0.0
8	-C.1138C03D CC	0.0
9	-C.1019534D CC	0.0
10	-C.9237994D-01	0.0
11	-C.844663CD-01	0.0
12	-C.7781442D-01	0.0
13	-C.7214252D-01	0.0
14	-C.6724742D-01	0.0
15	-0.6297978D-01	0.0

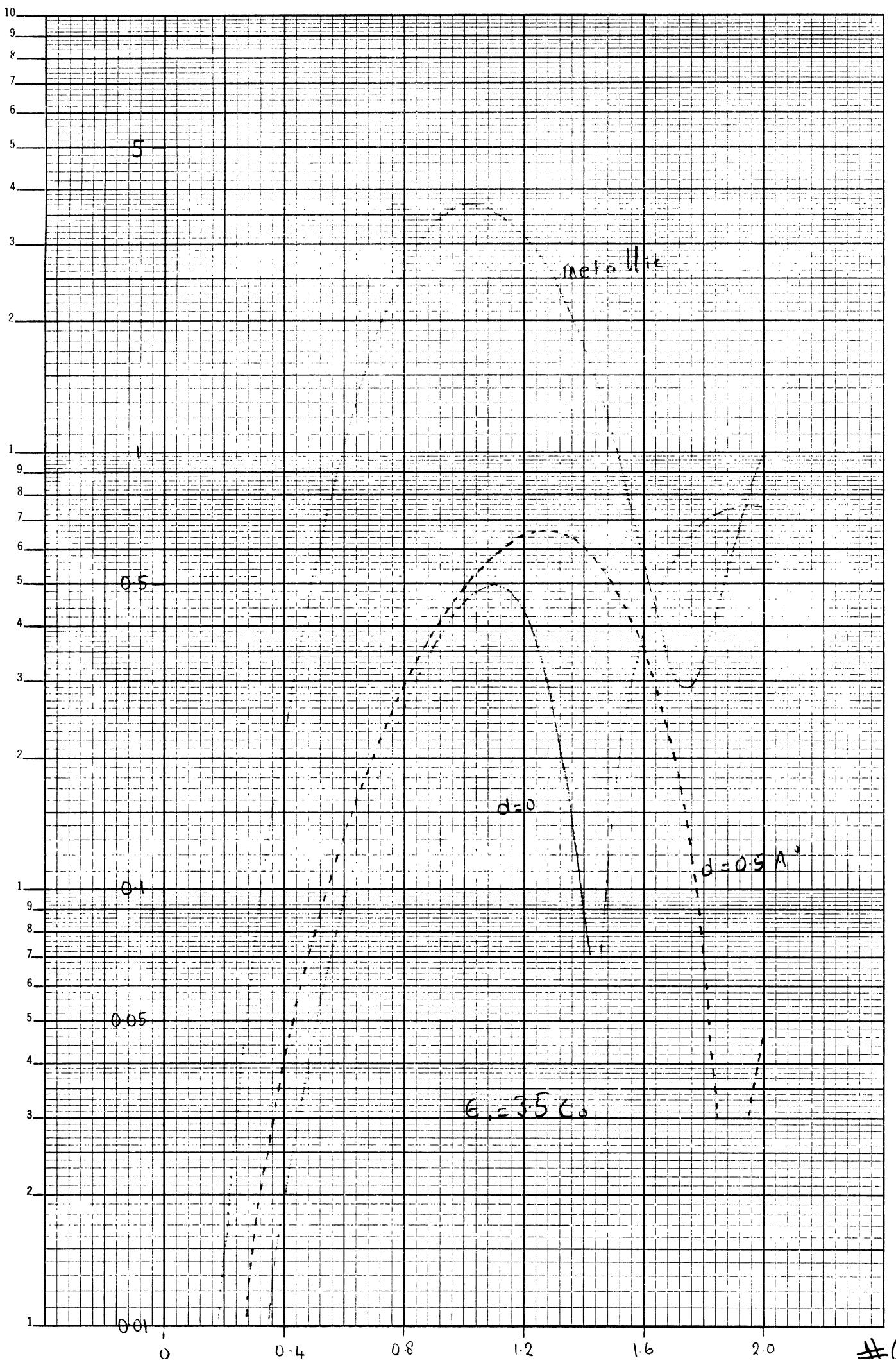
THF IMPEDANCE OF THF SURFACE LAYER IS -0.32917110-00 -0.6451613D-01  
 S(C) IS C.773731C4D 00 0.34765660D 00  
 S(PIE) IS C.34227153D 00 0.57947234D 00  
 S(C)\* IS C.322388C5D 00 0.17324210D 00  
 S(PIE)\* IS C.67997936D 00 0.19920757D 00  
 SIGMA(C)/N IS 2.873C993 , PHI IS 24.1955448 DEGREES  
 SIGMA(PIE)/N IS 1.814494 , PHI IS 59.358C184 DEGREES  
 SIGMA(C)\*\*/N IS 2.5357875 , PHI IS 28.2522821 DEGREES  
 SIGMA(PIE)\*\*/N IS 2.3682222 , PHI IS 16.32852C3 DEGREES  
 SPHERF WITH LAYER DEFECTRIC SPHERE  
 C.72211D-01 C.1924CD 00 0.30092D 00 -0.39702D 00 C.81419D-C2 -0.39855D-01  
 C.42846D-C2 C.15854D-01 C.27567D-02 -0.29972D-01 C.40229D-C5 -0.20057D-02 C.30793D-03 -0.17545D-01  
 C.19988D-C3 C.45954D-03 C.3C354D-04 -0.75295D-C3 0.90584D-C9 -0.30099D-04 0.19643D-C6 -0.44321D-03  
 C.38961D-C5 C.68240D-C5 C.33937D-05 -0.11385D-04 0.89211D-13 -0.29868D-06 0.44996D-10 -0.67079D-05  
 C.44C7D-C7 C.62546D-07 C.26951D-C8 -0.11208D-C6 0.43070D-17 -0.20753D-08 0.43668D-14 -C.66C81D-07  
 C.32734D-C9 C.39037D-C9 C.15573D-10 -0.77179D-C9 0.11279D-21 -0.16629D-10 C.2C704D-18 -C.45501D-09  
 C.17235D-11 C.17777D-11 C.68123D-13 -C.39094D-11 0.17336D-26 -0.41636D-13 0.53316D-23 -0.23096D-11  
 C.67879D-14 C.61635D-14 C.23304D-15 -0.15201D-13 0.1635D-31 -0.12898D-15 C.8C762D-28 -C.89868D-14  
 C.2C795D-16 C.16263D-16 C.64C93D-18 -0.46754D-16 C.16469D-36 -0.32356D-18 C.76533D-33 -C.27665D-16  
 C.51065D-19 C.37434D-19 C.14416D-20 -0.11656D-18 0.44975D-42 -0.67064D-21 0.47647D-38 -0.69027D-19  
 C.18296D-21 C.69314D-22 C.27106D-23 -0.24030D-21 C.13634D-47 -0.11677D-23 0.20279D-43 -0.14241D-21  
 C.17342D-24 C.19663D-24 C.43178D-26 -0.41642D-24 C.2993D-53 -C.17319D-26 C.67980D-49 -C.24694D-24  
 C.24928D-27 C.14127D-27 C.59012D-29 -0.61555D-27 C.49029D-59 -C.22142D-29 C.13319D-54 -C.36495D-27  
 C.30589D-30 C.16197D-32 C.68950D-32 -C.78346D-30 C.6791D-65 -C.24656D-32 C.21635D-60 -C.46514D-30  
 C.32764D-33 C.16239D-33 C.7593D-35 -C.86951D-33 0.58202D-71 -0.24125D-35 C.26676D-66 -0.51649D-33

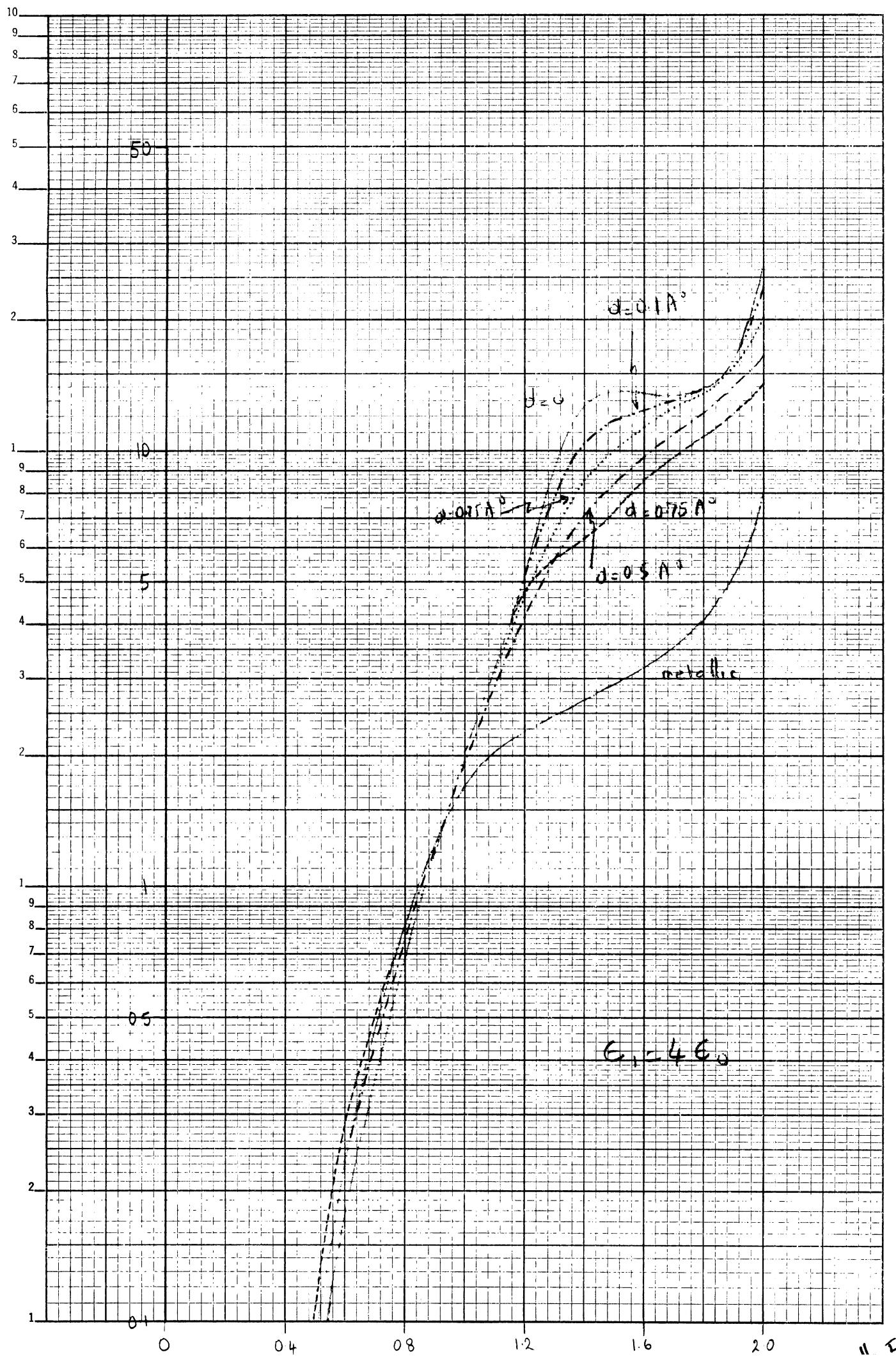
STOP C  
EXECUTION TERMINATED

**K+E** SEMI-LOGARITHMIC 46 5493  
3 CYCLES X 70 DIVISIONS MADE IN U.S.A.  
KEUFFEL & ESSER CO.

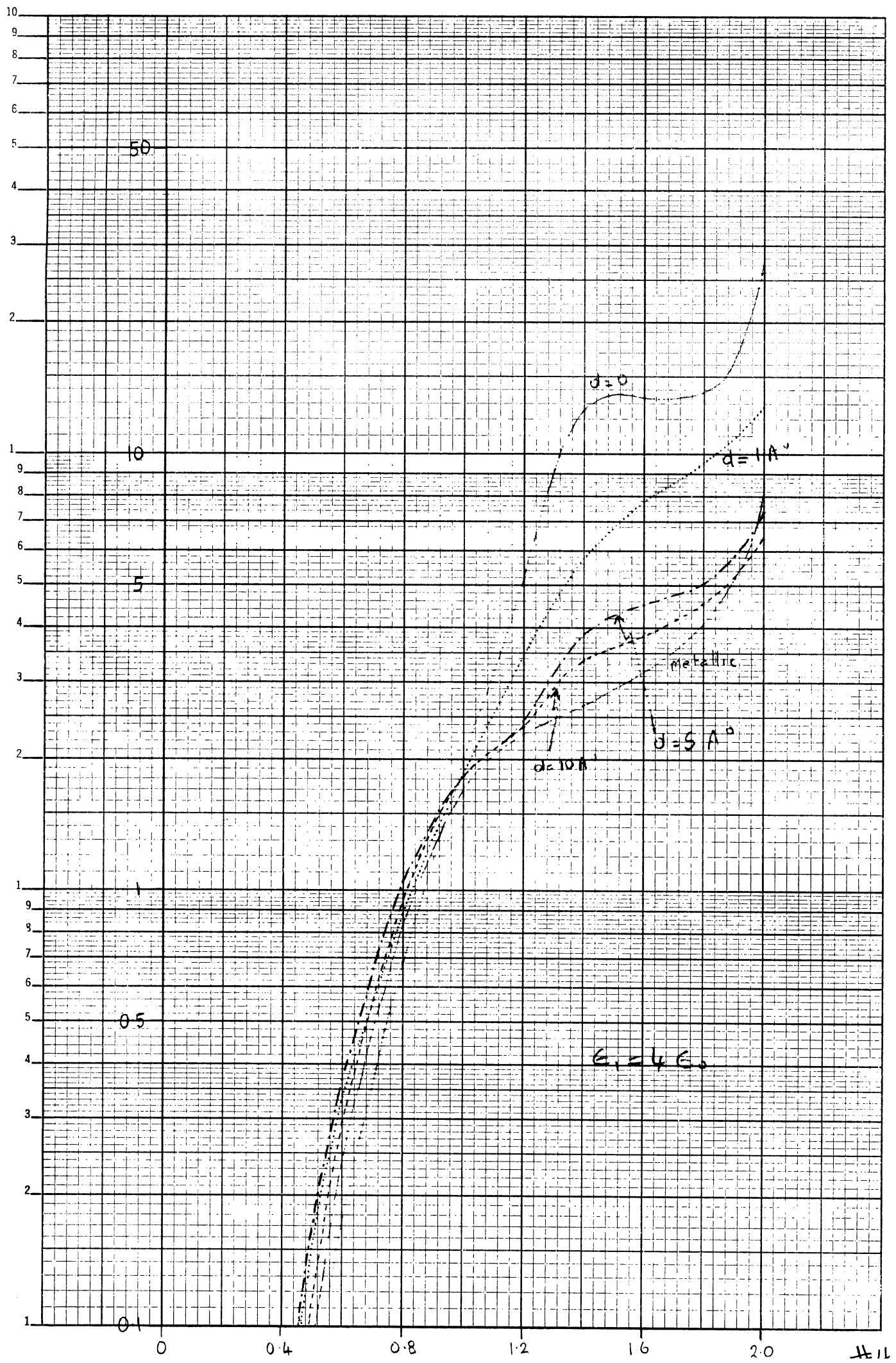


**K-E** SEMI-LOGARITHMIC 46 5493  
3 CYCLES X 70 DIVISIONS MADE IN U.S.A.  
KEUFFEL & ESSER CO.

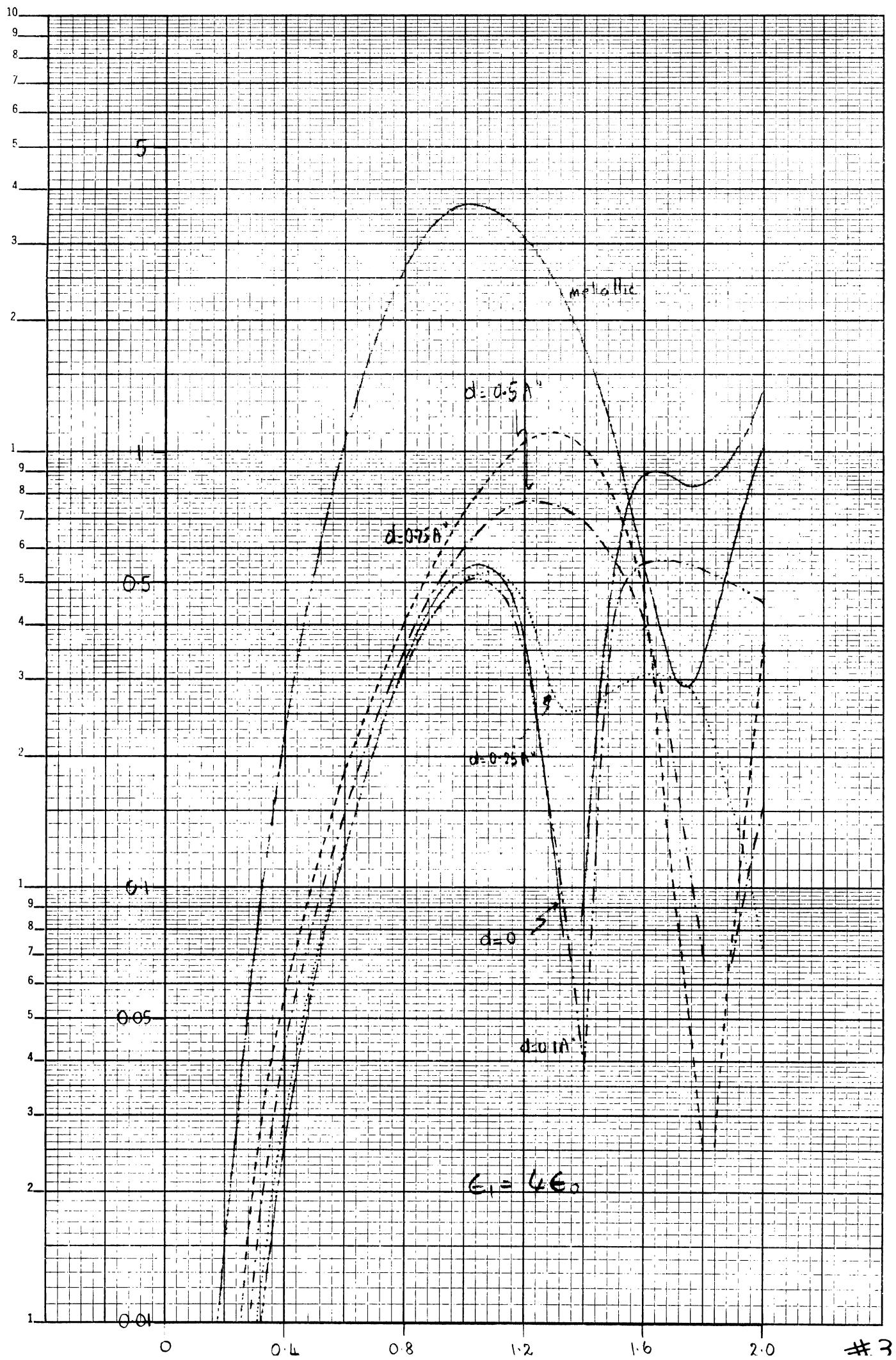




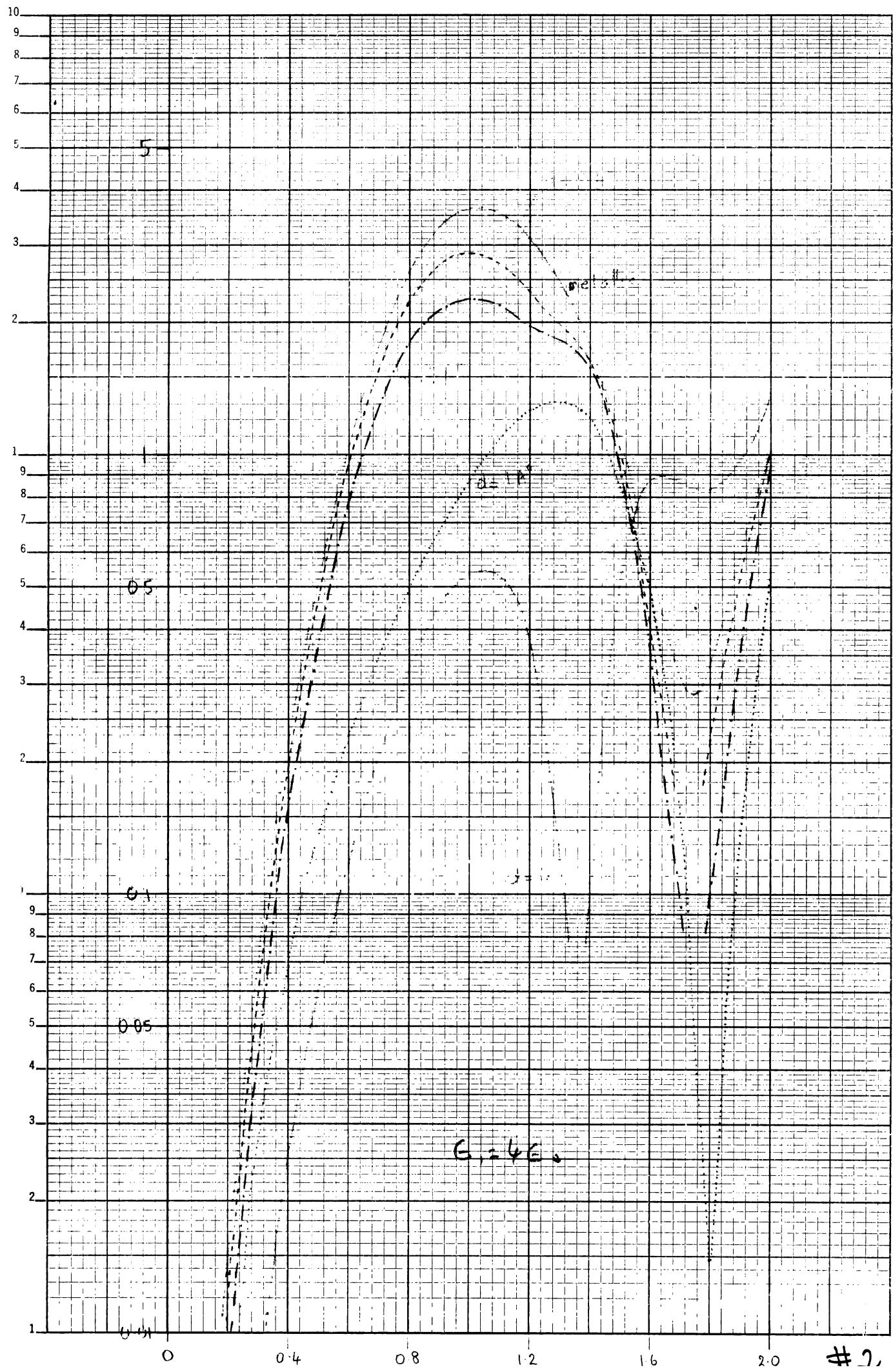
**K.E.** SEMI-LOGARITHMIC 46 5493  
3 CYCLES X 70 DIVISIONS MADE IN U.S.A.  
KEUFFEL & ESSER CO.



**K.E** SEMI-LOGARITHMIC 46 5493  
3 CYCLES X 70 DIVISIONS MADE IN U.S.A.  
KEUFFEL & ESSER CO.



**K** SEMI-LOGARITHMIC 46 5493  
3 CYCLES X 70 DIVISIONS MADE IN U.S.A.  
KEUFFEL & ESSER CO.



THE RADIUS OF THE INNER SPHERE IS 0.999900000000 METERS  
 THE RADIUS OF THE OUTER SPHERE IS 1.00000000 METERS  
 THE THICKNESS OF THE COATING IS 0.10000000D-03 METERS  
 THE PENETRATION DEPTH IS C.1135924D-04 METERS  
 THE COATING THICKNESS IS 0.8803408D 01 TIMES THE PENETRATION DEPTH

K0B IS 1.0000000

E2/E0 IS 0.1550000D 11

E1/E0 IS 0.4000000D 01

K0/K1 IS 0.5000000D 00 0.0

K0/K2 IS 0.5679618D-05 -0.5679618D-05

K2D IS 0.880340843111D 01 C.880340843055D 01

ORDER

	GAMMA-1	GAMMA-2
1	-0.5679618D-05	-0.5679618D-05
2	-0.5679618D-05	-0.5679618D-05
3	-0.5679618D-05	-0.5679618D-05
4	-0.5679618D-05	-0.5679618D-05
5	-0.5679618D-05	-0.5679618D-05
6	-0.5679618D-05	-0.5679618D-05
7	-0.5679618D-05	-0.5679618D-05
8	-0.5679618D-05	-0.5679618D-05
9	-0.5679618D-05	-0.5679618D-05
10	-0.5679618D-05	-0.5679618D-05
11	-0.5679618D-05	-0.5679618D-05
12	-0.5679618D-05	-0.5679618D-05
13	-0.5679618D-05	-0.5679618D-05
14	-0.5679618D-05	-0.5679618D-05
15	-0.5679618D-05	-0.5679618D-05

ORDER

	GAMMA-1*	GAMMA-2*
1	-0.9187552D 00	0.0
2	-0.4187552D 00	0.0
3	-0.2827840D 00	0.0
4	-0.2161349D 00	0.0
5	-0.1752781D 00	0.0
6	-0.1486099D 00	0.0
7	-0.1288373D 00	0.0
8	-0.1138003D 00	0.0
9	-0.1019584D 00	0.0
10	-0.9237994D-01	0.0
11	-0.8446530D-01	0.0
12	-0.7781442D-01	0.0
13	-0.7214252D-01	0.0
14	-0.6724742D-01	0.0
15	-0.6297878D-01	0.0

THE IMPEDANCE OF THE SURFACE LAYER IS -0.5679618D-05 -0.5679618D-05

S(0) IS 0.8796205CD 00 0.3683C756D 00

S(PIE)\* IS 0.40351678D 00 0.50898104D 00

S(0)\* IS 0.32239805D 00 0.17324210D 00

S(PIE)\* IS 0.67997936D 00 0.19920757D 00

SIGMA(C)/N IS 3.6375307 ,PHI IS 22.7196171 DEGREES

SIGMA(PIE)/N IS 1.6875500 ,PHI IS 51.5928005 DEGREES

SIGMA(C)\*/N IS 0.5357875 ,PHI IS 28.2522821 DEGREES

SIGMA(PIE)\*/N IS 2.0082223 ,PHI IS 16.3285203 DEGREES

SPHERE WITH LAYER

DIELECTRIC SPHERE

0.45353D-01	0.20807D 00	0.29193D 00	-0.45465D 00	0.81419D-02	-0.89865D-01	0.12414D 00	-0.32974D 00
0.29645D-03	0.17202D-01	0.92264D-03	-0.30358D-01	0.40229D-05	-0.20057D-02	0.30793D-03	-0.17545D-01
0.31333D-06	0.54113D-03	0.57398D-06	-0.75587D-03	0.90584D-09	-0.30097D-04	0.19643D-06	-0.44321D-03
0.52577D-09	0.89547D-05	0.16027D-09	-0.11409D-04	0.89211D-13	-0.29968D-06	0.44996D-10	-0.67079D-05
0.56942D-11	0.92607D-07	0.25067D-12	-0.11224D-06	0.43070D-17	-0.20753D-08	0.43668D-14	-0.66081D-07
0.47969D-13	0.65770D-09	0.13749D-14	-0.77185D-09	0.11279D-21	-0.10620D-10	0.20704D-18	-0.45501D-09
0.28789D-15	0.34102D-11	0.60080D-17	-0.39123D-11	0.17336D-26	-0.41636D-13	0.53316D-23	-0.23090D-11

0.12928D-17	0.13484D-13	0.20545D-19	-0.15210D-13	0.16635D-31	-0.12898D-15	0.80762D-28	-0.89868D-1
0.45088D-20	0.42018D-16	0.56409D-22	-0.46776D-16	0.10469D-36	-0.32356D-18	0.76533D-33	-0.27665D-1
0.12568D-22	0.10585D-18	0.12703D-24	-0.11661D-18	0.44975D-42	-0.67064D-21	0.47647D-38	-0.69027D-1
0.28642D-25	0.22009D-21	0.23881D-27	-0.24038D-21	0.13634D-47	-0.11677D-23	0.20279D-43	-0.14241D-2
0.54368D-28	0.38413D-24	0.38036D-30	-0.41653D-24	0.29993D-53	-0.17319D-26	0.60980D-49	-0.24694D-2
0.87291D-31	0.57080D-27	0.51979D-33	-0.61519D-27	0.49029D-59	-0.22142D-29	0.13319D-54	-0.36495D-2
0.12010D-33	0.73C88D-30	0.61679D-36	-0.78361D-30	0.60791D-65	-0.24656D-32	0.21535D-60	-0.46514D-3
0.14317D-36	0.81483D-33	0.63934D-39	-0.96966D-33	0.58202D-71	-0.24125D-35	0.26676D-66	-0.51649D-3

STOP C  
EXECUTION TERMINATED